



EDMI Microsystems and Microelectronics

MICRO-614: Electrochemical Nano-Bio-Sensing
and Bio/CMOS interfaces

Lecture #7

Checking Probes-layer quality (RM+SPR+SEM+AFM)

Lecture Outline

(Book Bio/CMOS: Chapter' paragraphs § 5.2.1-2)

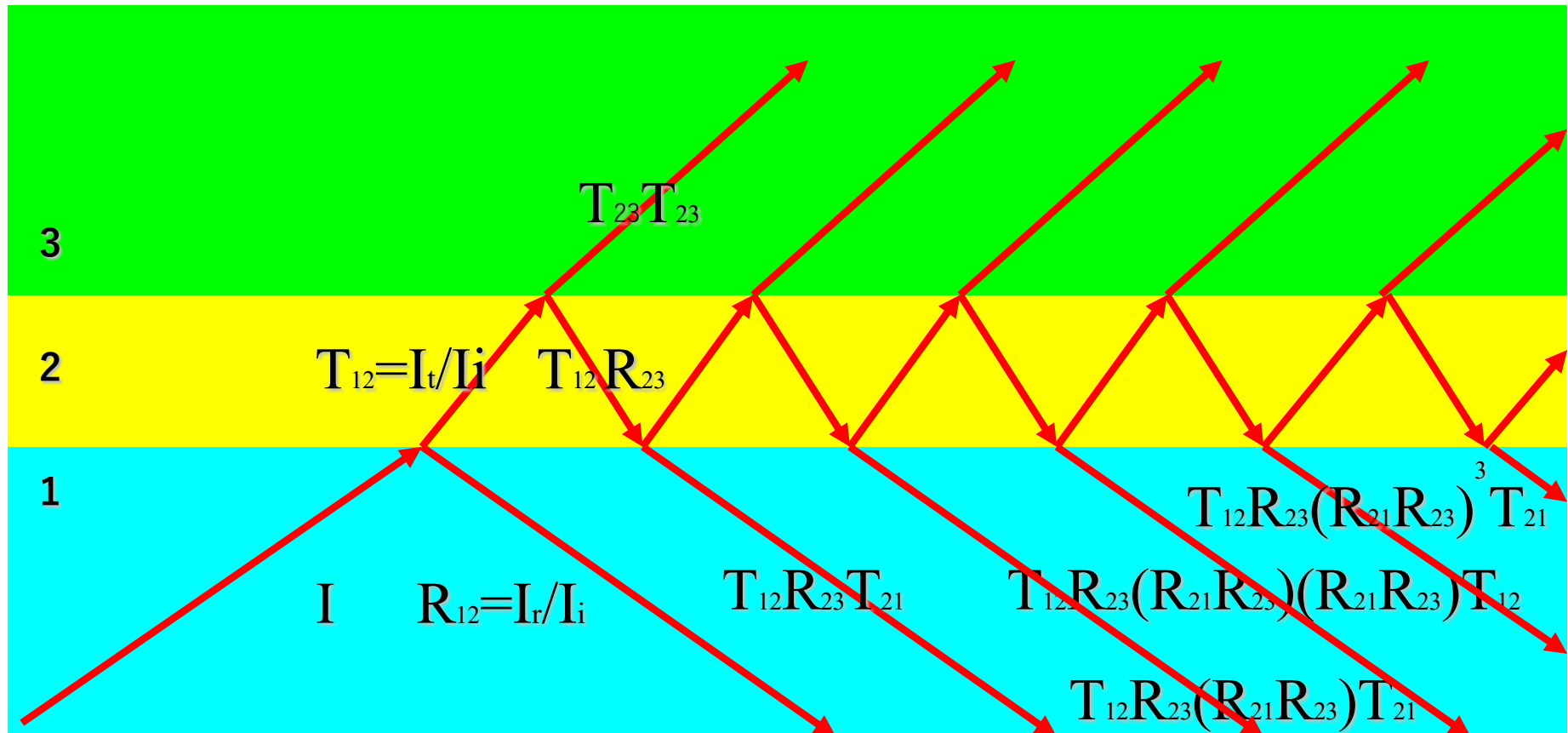
- Resonant Mirror
- Surface Plasmon Resonance

To monitor the self-assembly process

- Transmission Electron Microscopy
- Scanning Electron Microscopy
- Atomic Force Microscopy
- Scanning Tunneling Microscopy

To check the film quality

Three-layers Reflection



$$R = R_{12} + T_{12}R_{23}T_{21} + T_{12}R_{23}T_{21}(R_{21}R_{23}) + T_{12}R_{23}T_{21}(R_{21}R_{23})^2 + \dots$$

Three-layers Reflection

$$R = R_{12} + T_{12}R_{23}T_{21} + T_{12}R_{23}T_{21}(R_{21}R_{23}) + T_{12}R_{23}T_{21}(R_{21}R_{23})^2 + \dots$$

$$R = R_{12} + \sum_{n=0}^{\infty} T_{12}R_{23}T_{21}(R_{21}R_{23})^n$$

$$R = R_{12} + T_{12}R_{23}T_{21} \sum_{n=0}^{\infty} (R_{21}R_{23})^n$$

By the geometric series

$$\sum_{n=0}^{\infty} x^n = \frac{1}{1-x}$$

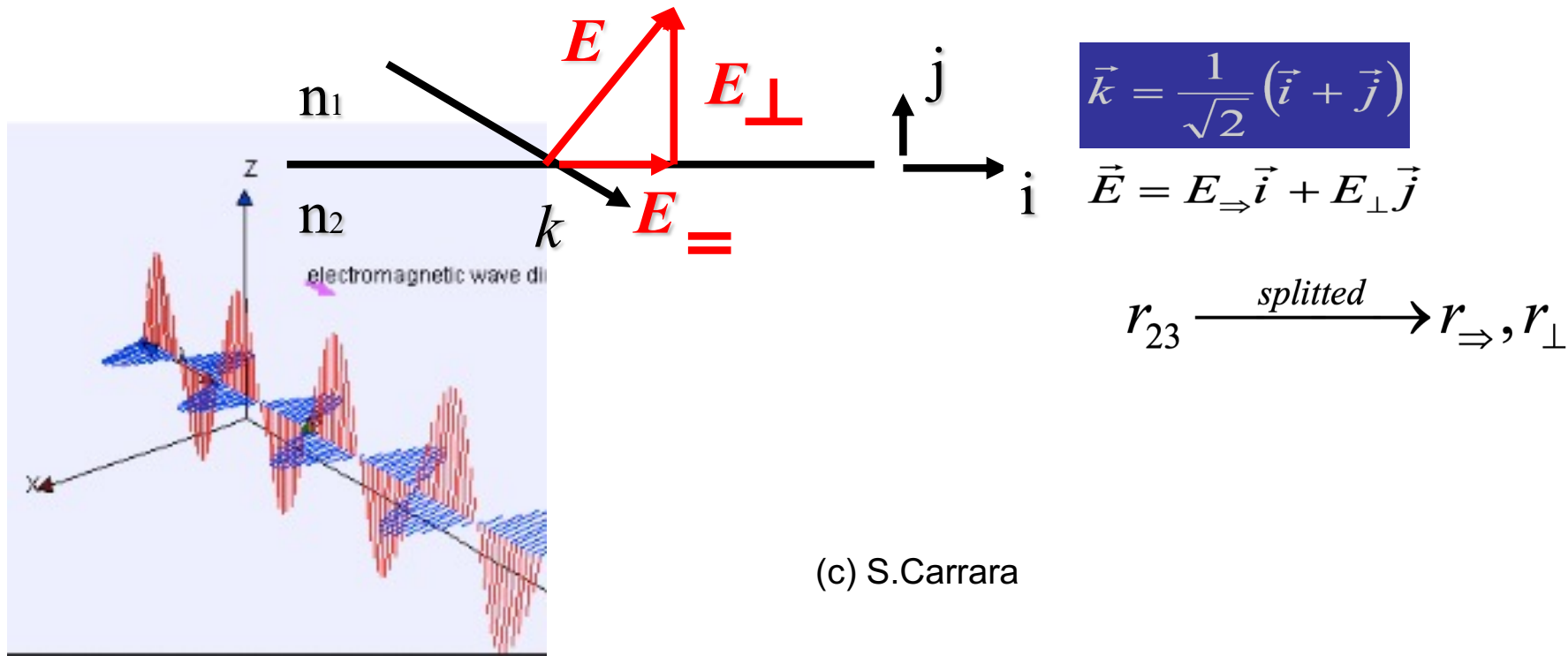
$$R = R_{12} + T_{12}R_{23}T_{21} \frac{1}{1-R_{21}R_{23}}$$

The Reflection coefficient and the Electrical Field

$$R = R_{12} + \frac{T_{12} R_{23} T_{21}}{1 - R_{21} R_{23}}$$

$$R_{23} = |r_{23}|^2$$

$$R_{23} = \frac{I_r}{I_i}; r_{23} = \frac{E_r}{E_i}$$



The Fresnel Coefficients

$r_{23} \xrightarrow{\text{splitted}} r_{\Rightarrow}, r_{\perp}$

$r_{23\Rightarrow} = \frac{n_3 \cos(\vartheta_2) - n_2 \cos(\vartheta_3)}{n_3 \cos(\vartheta_2) + n_2 \cos(\vartheta_3)}$

$r_{23\perp} = \frac{n_2 \cos(\vartheta_2) - n_3 \cos(\vartheta_3)}{n_2 \cos(\vartheta_2) + n_3 \cos(\vartheta_3)}$

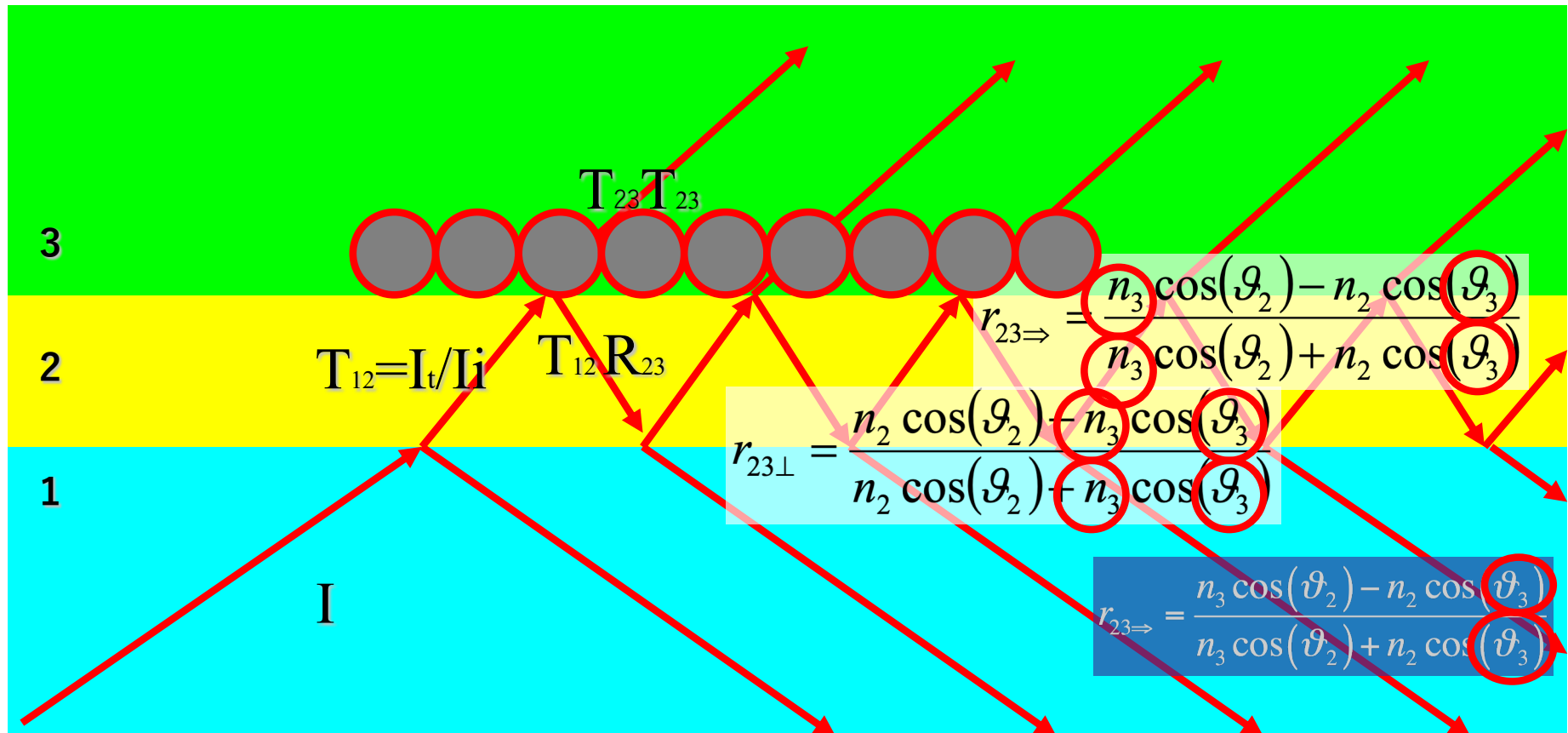
$t_{23} \xrightarrow{\text{splitted}} t_{\Rightarrow}, t_{\perp}$

$t_{23\Rightarrow} = \frac{2n_2 \cos(\vartheta_2)}{n_3 \cos(\vartheta_2) + n_2 \cos(\vartheta_3)}$

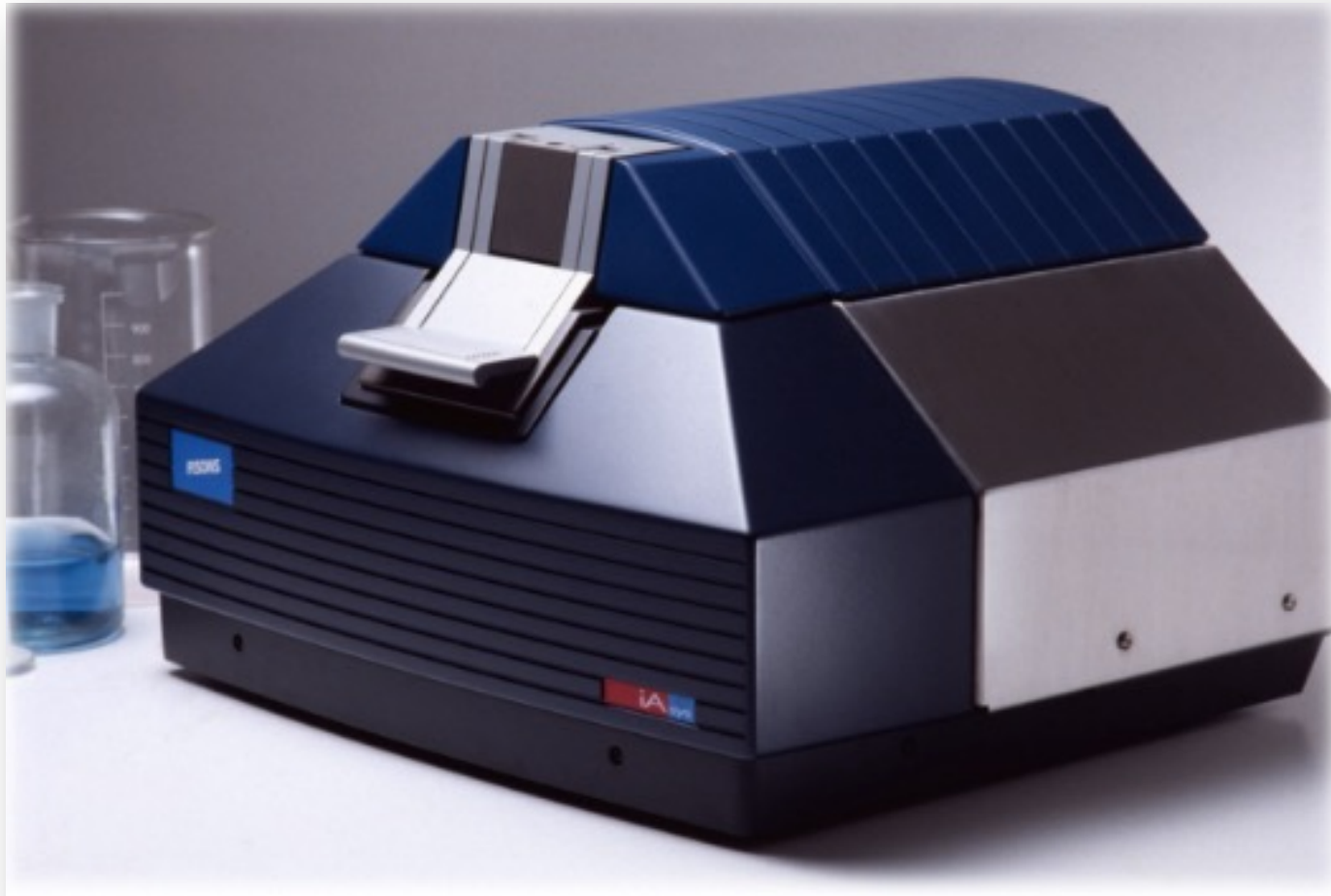
$t_{23\perp} = \frac{2n_2 \cos(\vartheta_2)}{n_2 \cos(\vartheta_2) + n_3 \cos(\vartheta_3)}$

$n_2 \sin(\vartheta_2) = n_3 \sin(\vartheta_3)$ **Snell's Law**

Three-layers Reflection



Product

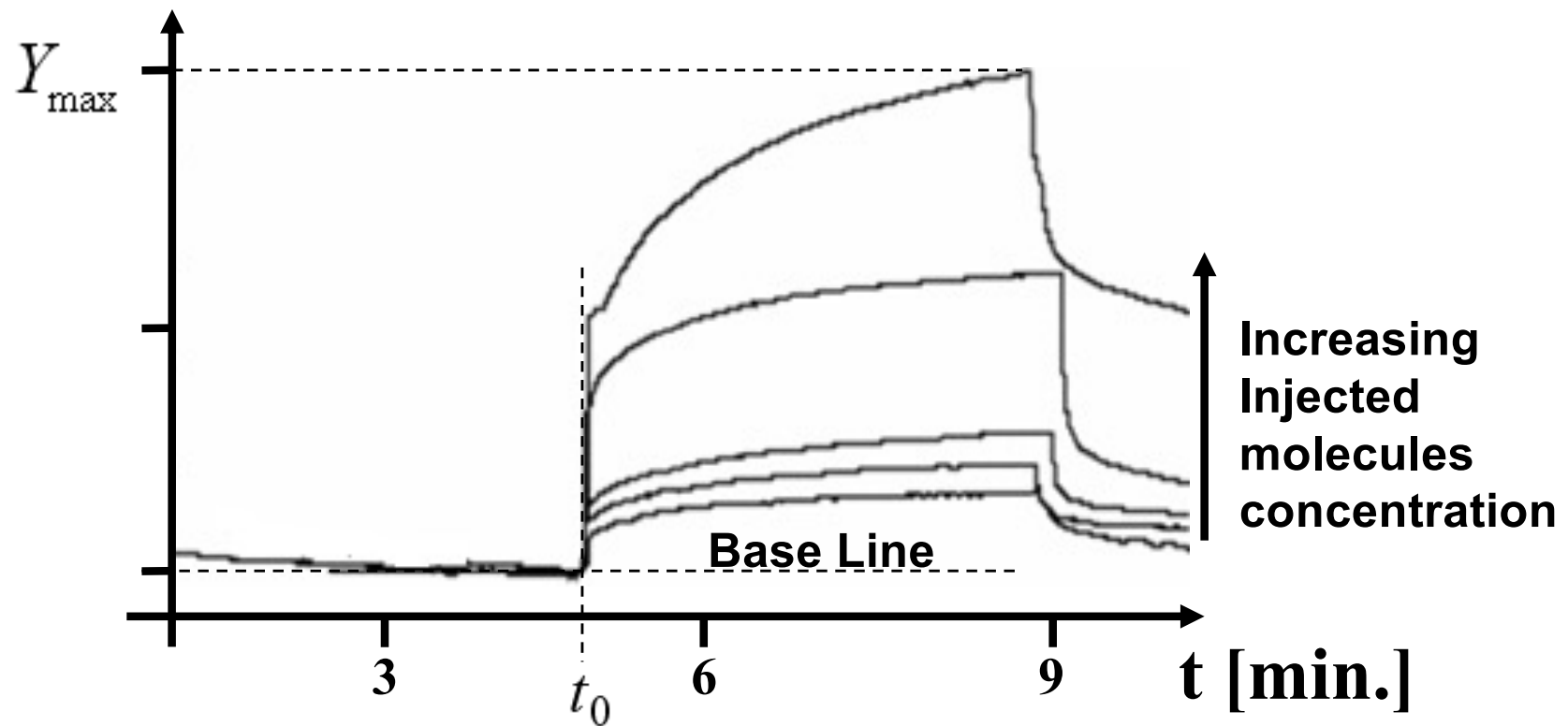


***IAsys plus* Affinity Sensor**

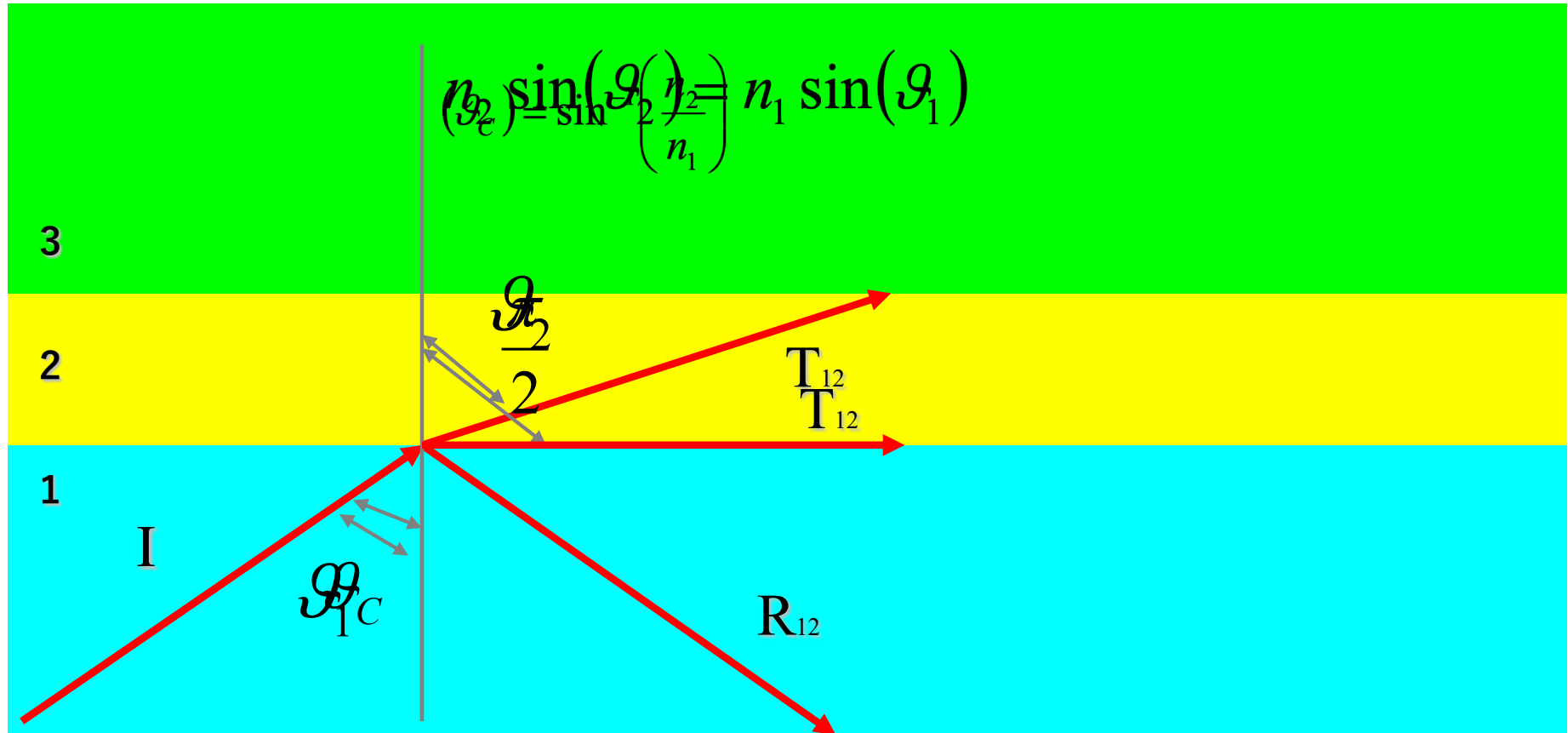
(c) S.Carrara

Yield Monitoring

Yield = Percentage of covered surface



Three-layers Reflection



The Propagation along the interface

Diagram illustrating the geometry of a dielectric interface at $z=0$ separating medium n_1 (bottom) and medium n_2 (top). An incident wave E_i with wave vector k approaches the interface. A reflected wave E_r and a transmitted wave E_t are shown. The transmitted wave E_t is parallel to the interface. The wave vector k is shown with its components k_x and k_z . The wave vector k is shown with its components k_x and k_z . The wave vector k is shown with its components k_x and k_z .

$$E_t = E_{0t} e^{ik_x x + ik_{pz} z - i\omega t}$$

$$k_{pz} = \sqrt{k_0^2 \epsilon_p - k_x^2}$$

$$\begin{cases} k_0 = \omega / c = 2\pi / \lambda \\ k_x = k_0 \sqrt{\epsilon_p} \sin(\vartheta) \\ n_2 = \sqrt{\epsilon_p \mu_p} \end{cases}$$

$$E_i = E_{0i} e^{ik_x x + ik_z z - i\omega t} \quad E_r = E_{0r} e^{ik_x x - ik_z z - i\omega t}$$

The Evanescent wave

$$E_t = E_{0t} e^{ik_x x + ik_{pz} z - i\omega t}$$

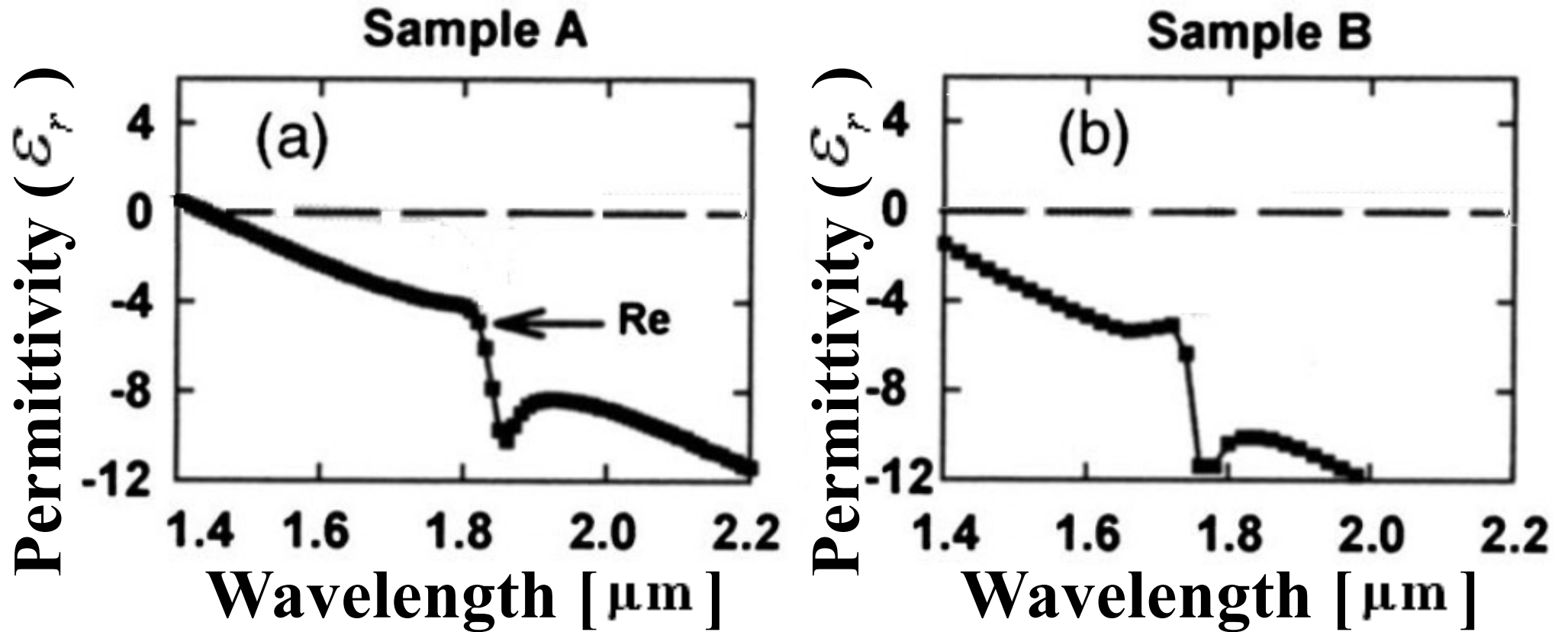
$$k_{pz} = \sqrt{k_0^2 \epsilon_p - k_x^2}$$

$\epsilon_p \leq 0$

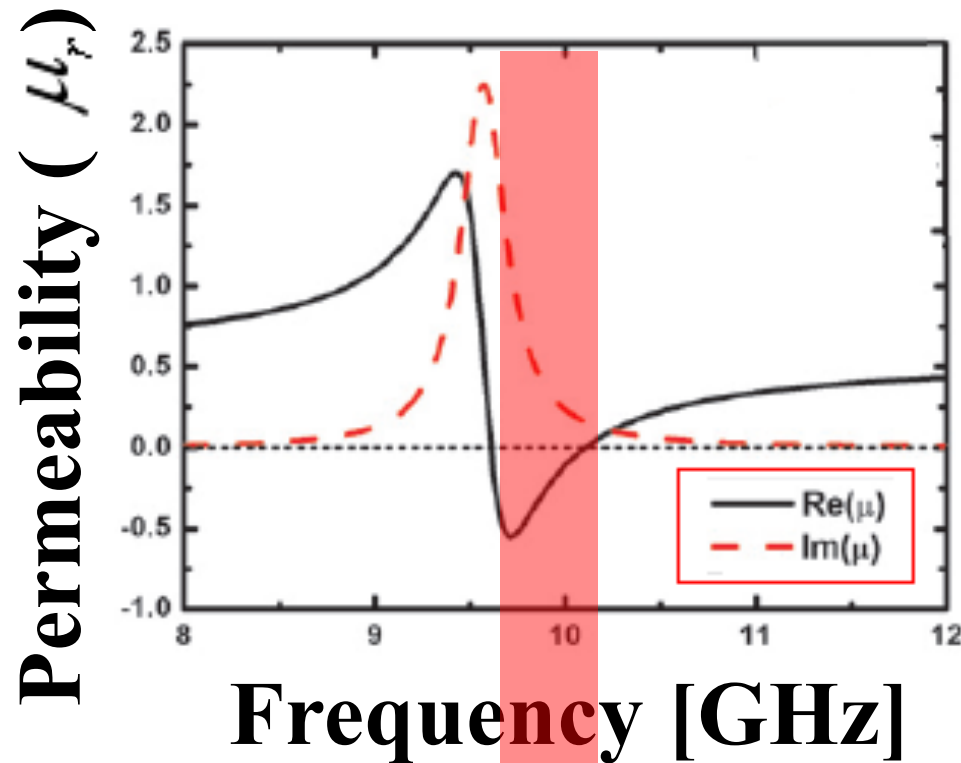
$$E_t = \left(E_{0t} e^{-|k_{pz}|z} \right) e^{ik_x x - i\omega t}$$

Negative Permeability of metals

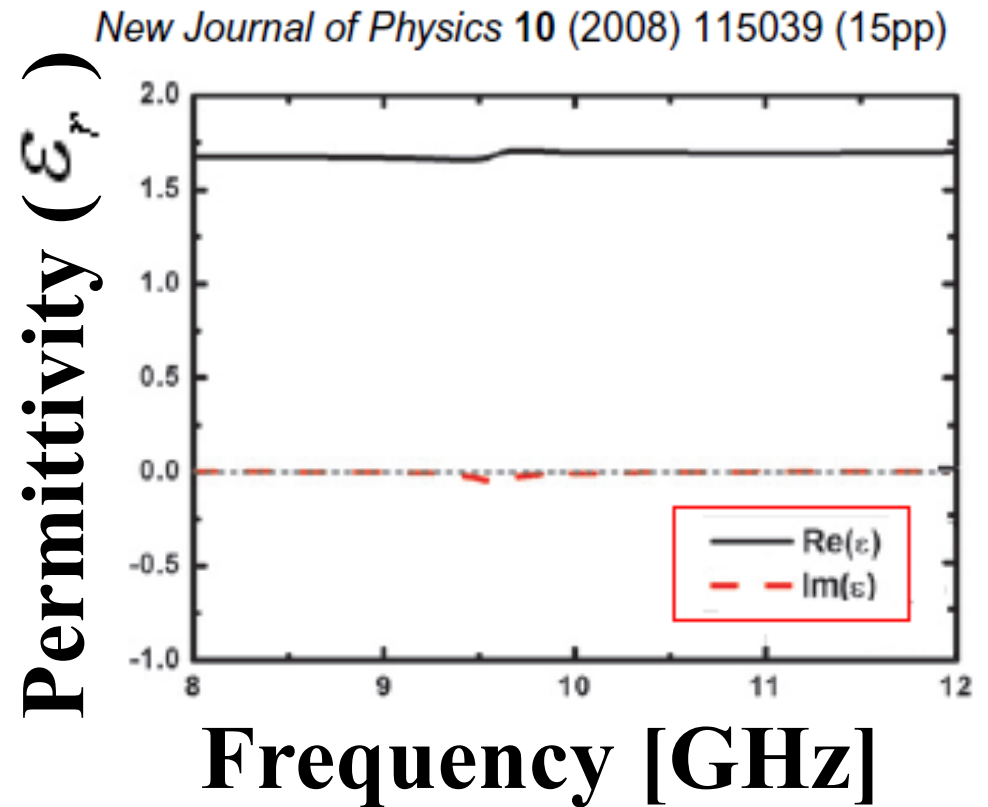
Zhang *et al.* J. Opt. Soc. Am. B/Vol. 23, No. 3/March 2006 pag 434



Negative Permittivity in metallic clots



Region of frequencies
with negative permeability

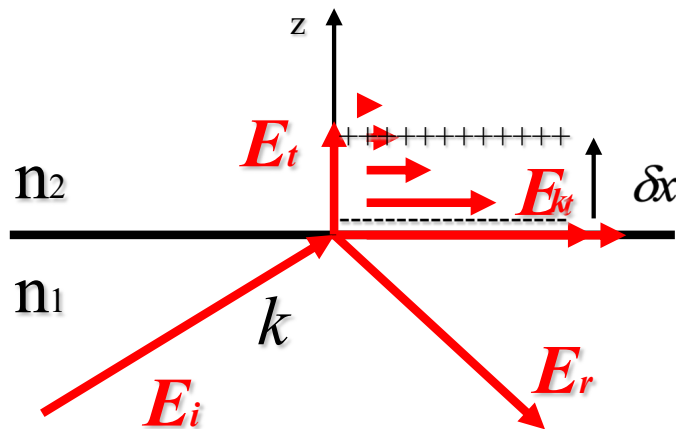


Negative dielectric constant

$$E_t = \left(E_{0t} e^{-|k_{pz}|z} \right) e^{ik_x x - i\omega t}$$

$$\varepsilon_p \leq 0$$

!



$$F = ma = m \frac{\partial^2 \delta x}{\partial t^2}$$

$$F = eE_t = -eE_{\delta x} = -e \frac{\sigma}{\varepsilon_0}$$

$$F = -e \frac{en_e \delta x}{\varepsilon_0}$$

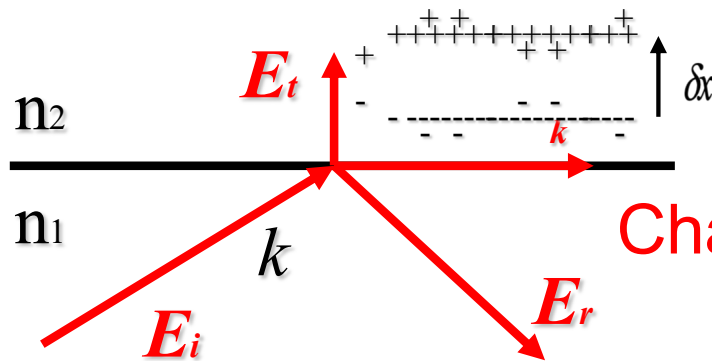
$$\frac{\partial^2 \delta x}{\partial t^2} + \frac{e^2 n_e \delta x}{m \varepsilon_0} = 0$$

$$\omega_p^2 = \frac{e^2 n_e}{m \varepsilon_0} \leftarrow \frac{\partial^2 \varphi}{\partial t^2} - \frac{e^2 n_e}{m \varepsilon_0} \varphi = 0$$

Electronic Waves

$$\frac{\partial^2 \delta x}{\partial t^2} + \omega_p^2 \delta x = 0 \longrightarrow \delta x = \delta x_0 e^{-i\omega_p t} = \frac{\epsilon_0 E_{0t} e^{-|k_{pz}|z_p}}{e} e^{-i\omega_p t}$$

The Plasmon!



Characteristic of the metal

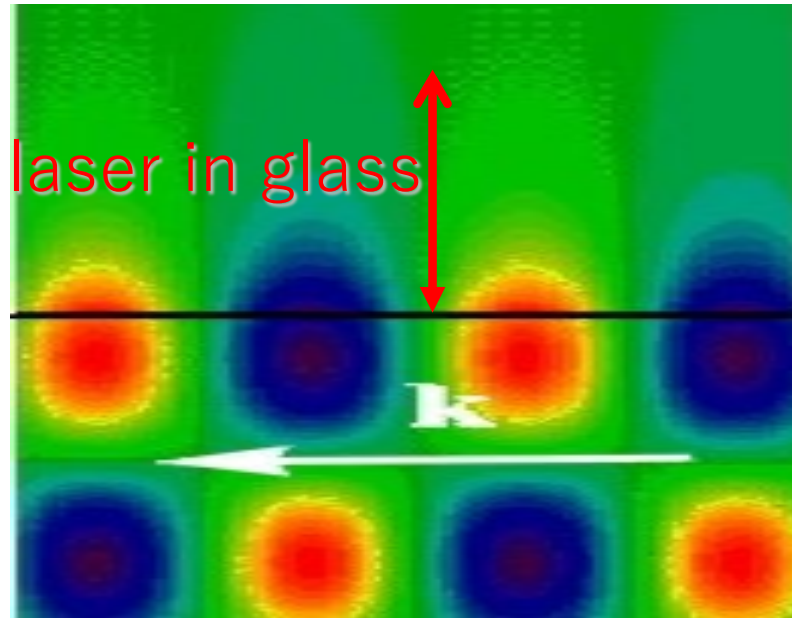
$$\omega_p^2 = \frac{e^2 n_e}{m \epsilon_0}$$

$$k_{pz} = \sqrt{k_0^2 \epsilon_p - k_x^2}$$

Characteristic of the evanescent wave

Simulation of Evanescent wave propagation

410 nm for HeNe laser in glass



Penetration of the Evanescent Wave

For an amplitude of 1/3 of the value in $z=0$, we have

$$E_{ot}e^{-|k_{mz}|z} = \frac{1}{3}E_t|_{z=0} = \frac{1}{3}E_{0t} \longrightarrow e^{-|k_{mz}|z} = \frac{1}{3} \approx \frac{1}{e}$$

By extracting z :

$$z = \frac{1}{|k_{mz}|} = \frac{c_0}{2\pi f \sqrt{|\mu_r \epsilon_r|}} = \frac{\lambda}{\sqrt{|\mu_r \epsilon_r|}}$$

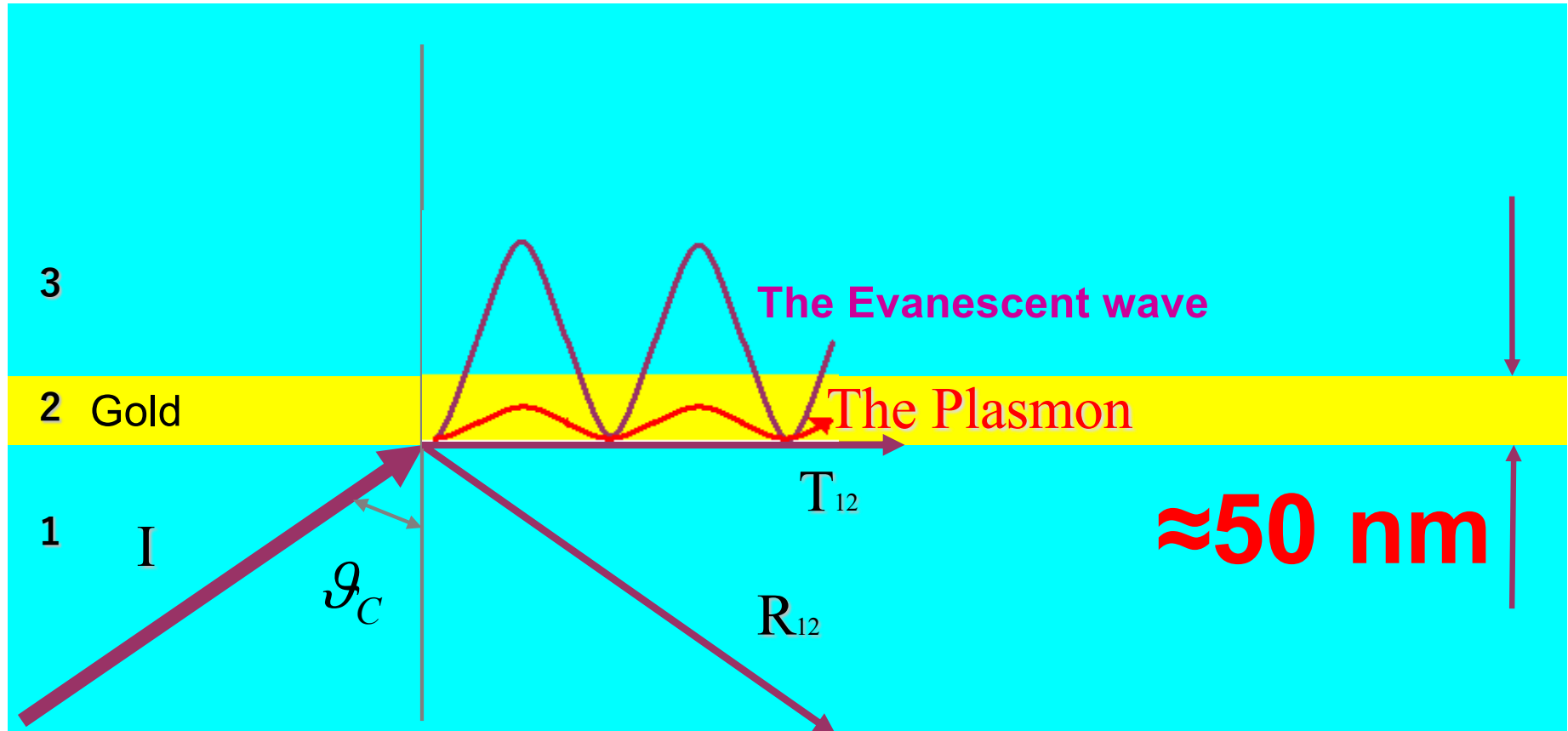
For gold, with relative magnetic permeability close to one and relative electric permittivity equal to 6.9, we obtain a thickness of

$$z_{gold} = \frac{1}{|k_{mz}|} = \frac{\lambda}{\sqrt{|\mu_r \epsilon_r|}} = \frac{400 \text{ nm}}{\sqrt{6.9 \cdot 1}} \approx 152 \text{ nm}$$

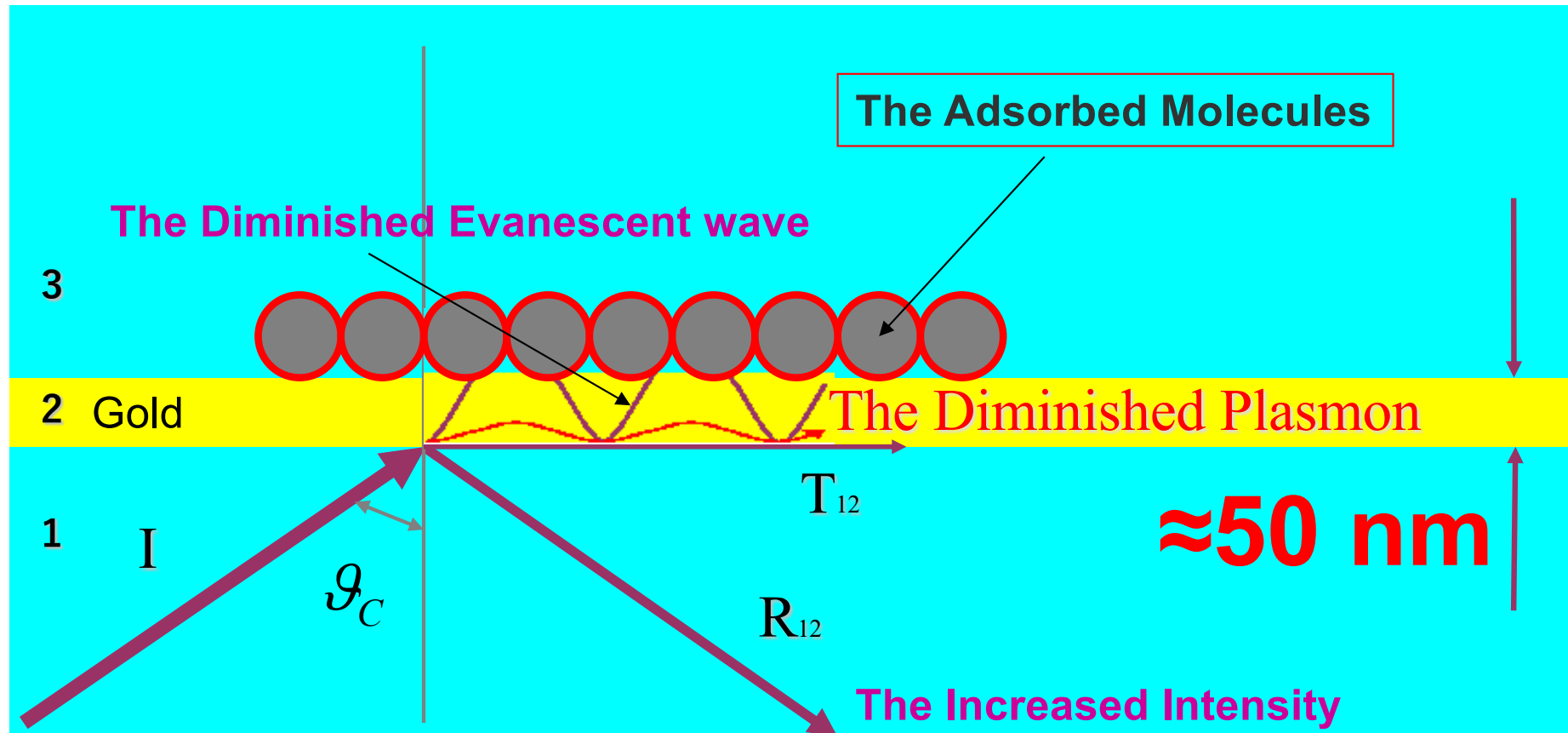
For nickel, with permeability and permittivity equal to 100 and 10 (respectively), we get:

$$z_{nickel} = \frac{1}{|k_{mz}|} = \frac{\lambda}{\sqrt{|\mu_r \epsilon_r|}} \approx \frac{400 \text{ nm}}{\sqrt{100 \cdot 10}} \approx 12 \text{ nm}$$

Penetration of the Evanescent Wave



Perturbation of the Evanescent Wave

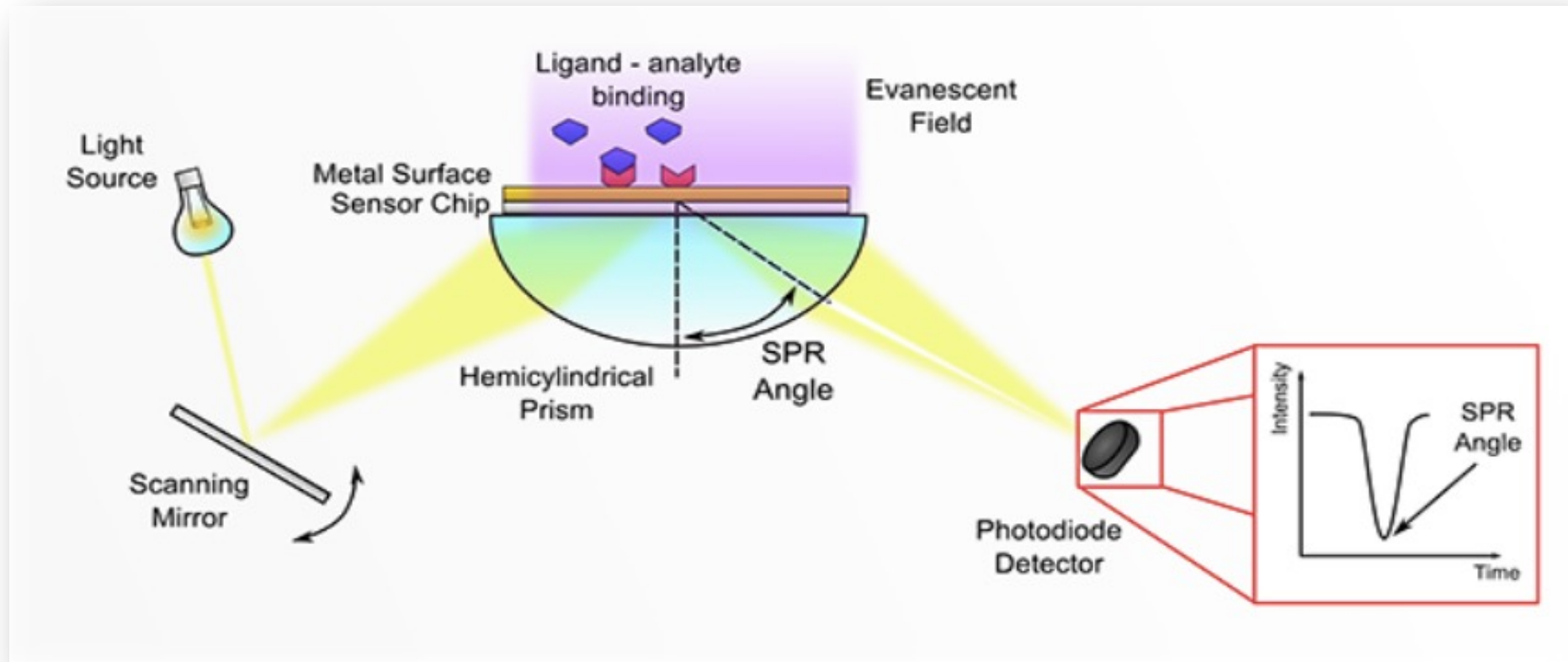


A Plasmon Resonance based Biosensor



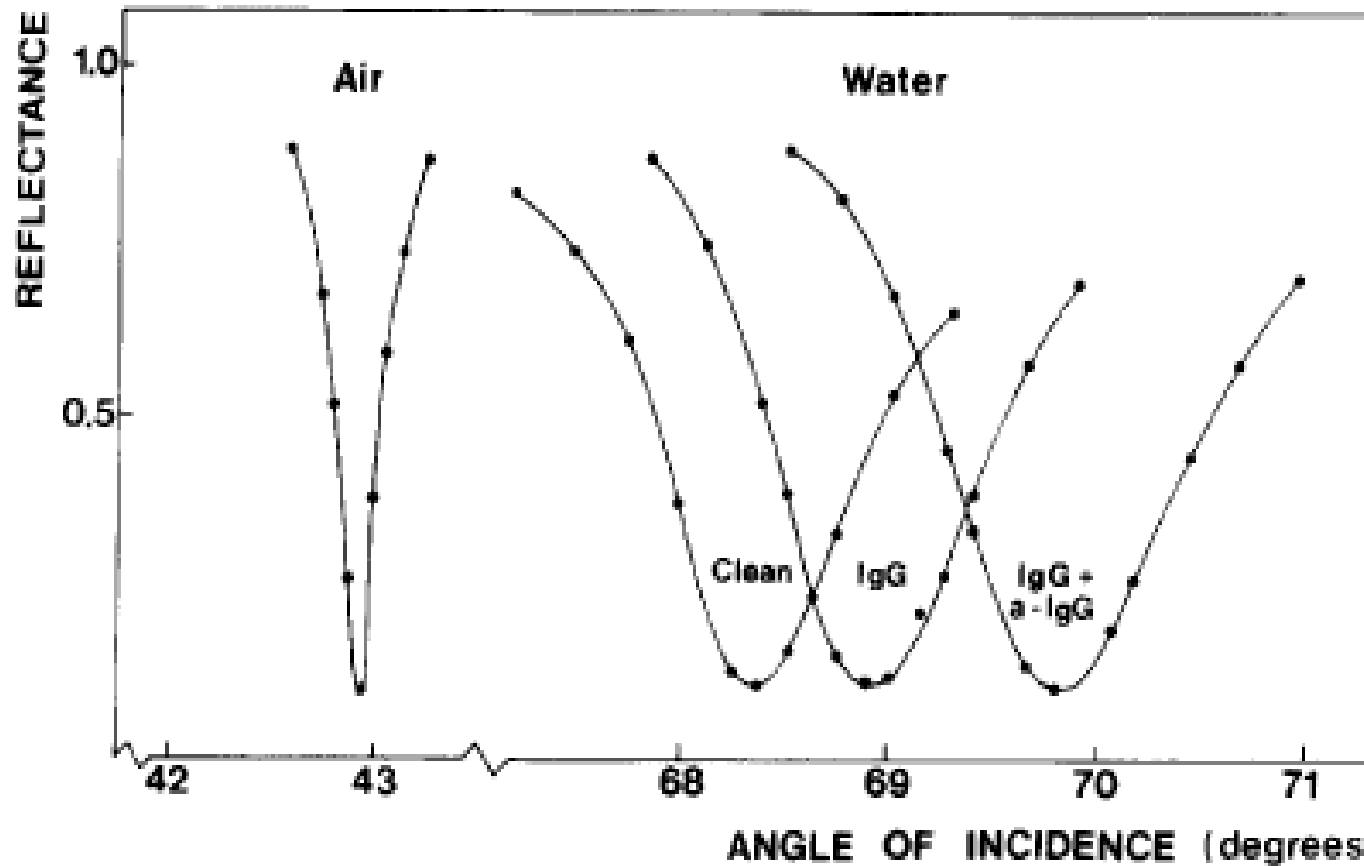
BIACORE 3000

Working Principle



The presence of the complexes onto the gold surface will change the angle of resonance for the formation of the Surface Plasmon.

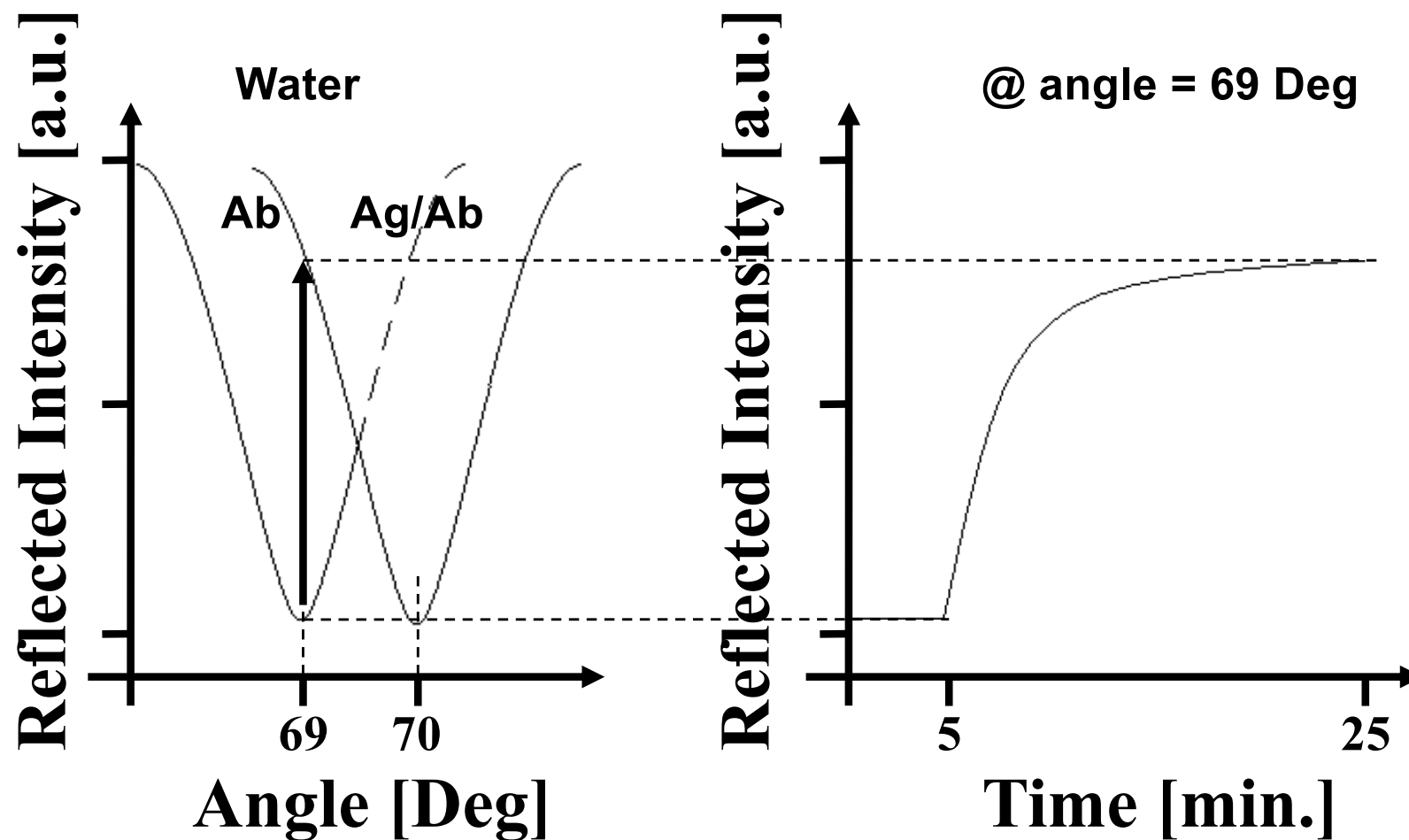
Characterization of Monoclonal antibodies



Bo Liedberg, et al, Biosensors & Bioelectronics 10 (1995) i-iv

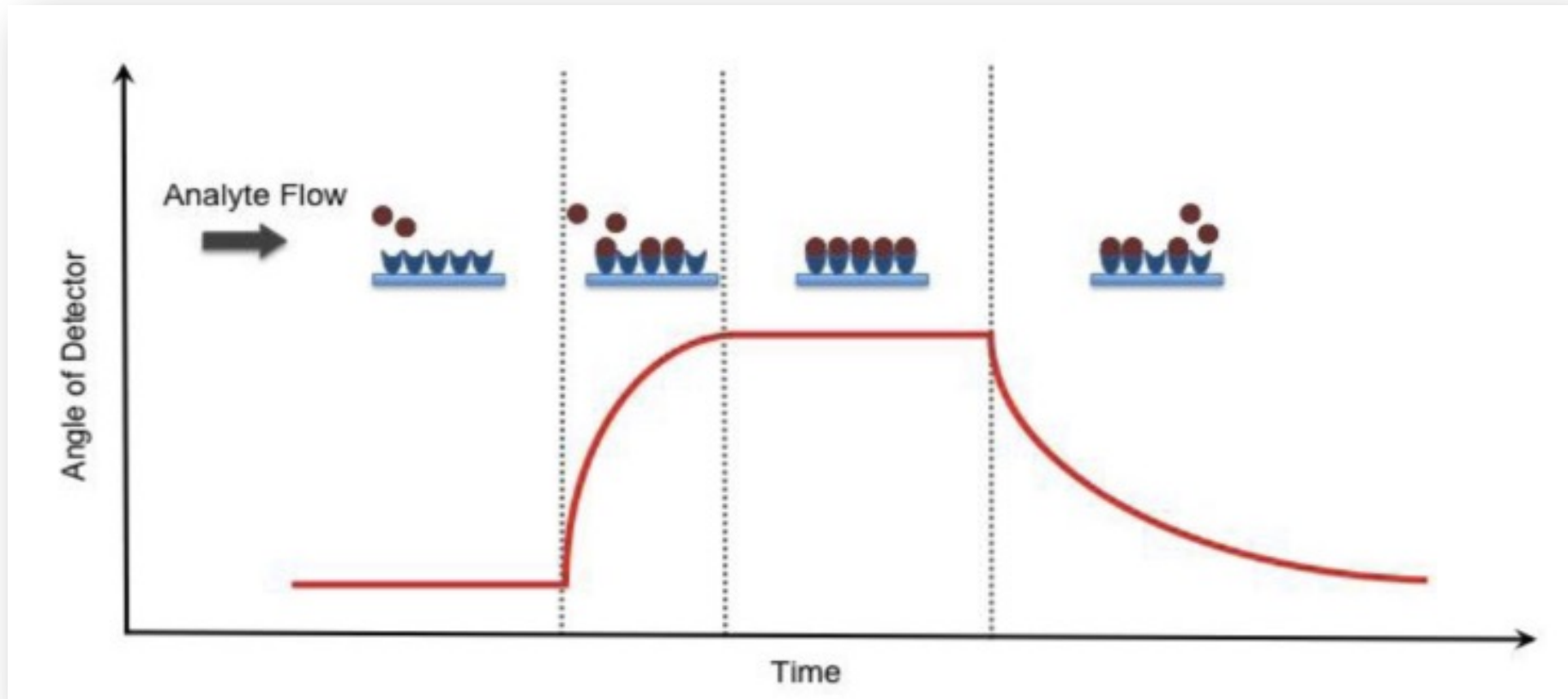
Shift in the resonant angle to sense IgG adsorption

Kinetic Studies



The kinetics could be reached by means of the change of the reflected intensity at fixed angle

Detection of Binding Events



Molecular uptake as monitored by SPR

SPR on SAM

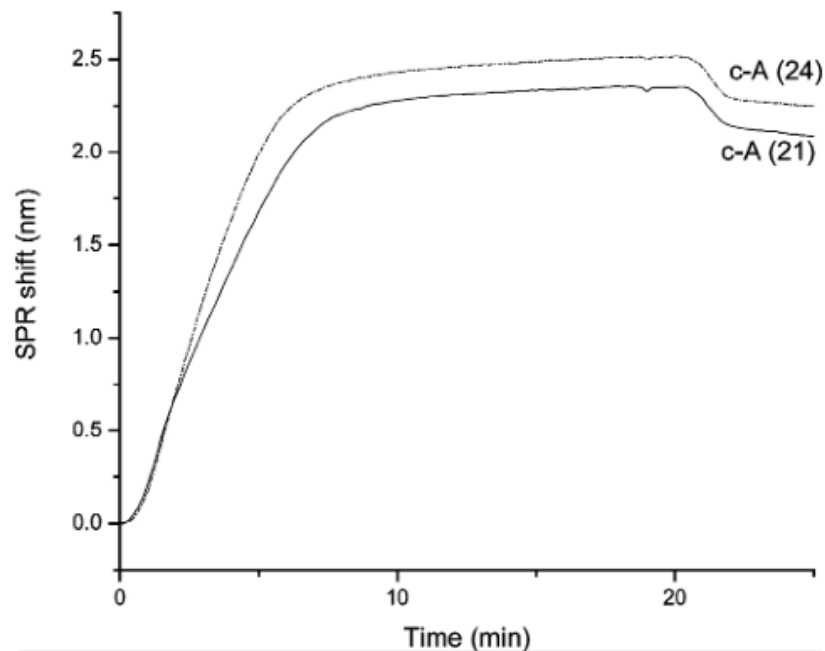


Figure 7. Comparison of the hybridization of a truncated complement (c-A 21) with the hybridization of the full-length complement (c-A 24). The ssDNA/OEG surface was prepared from a solution with a DNA mole fraction of 0.02.

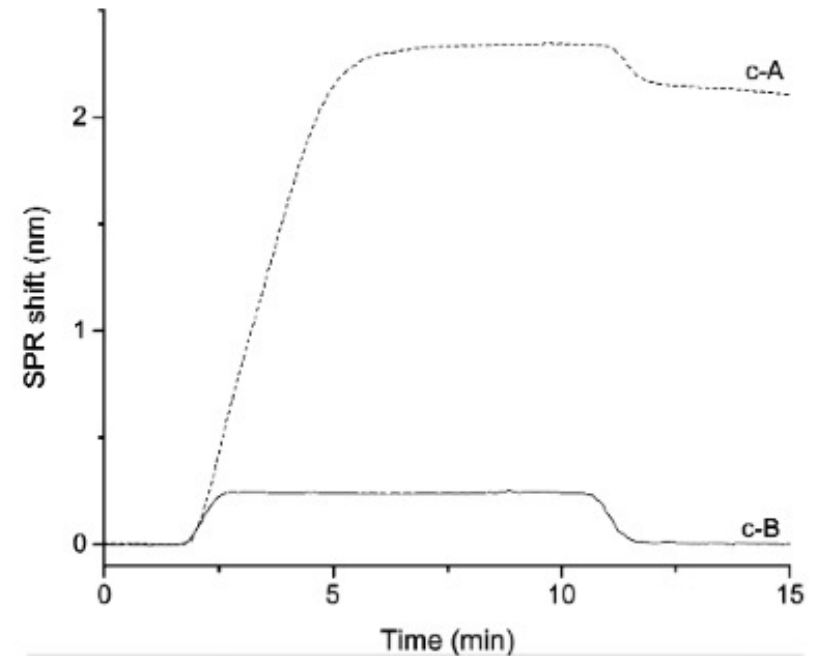


Figure 2. Control experiment to test DNA specificity. Both c-A and c-B were flowed over a sequence A ssDNA/OEG SAM, but only the complementary DNA hybridized. The ssDNA/OEG surface was prepared from a solution with a DNA mole fraction of 0.02.

Langmuir, Vol. 22, No. 10, 2006

DNA hybridization as monitored by SPR

How to characterize the Probes Immobilization?

We have seen what are the
mechanisms of self-assembly!

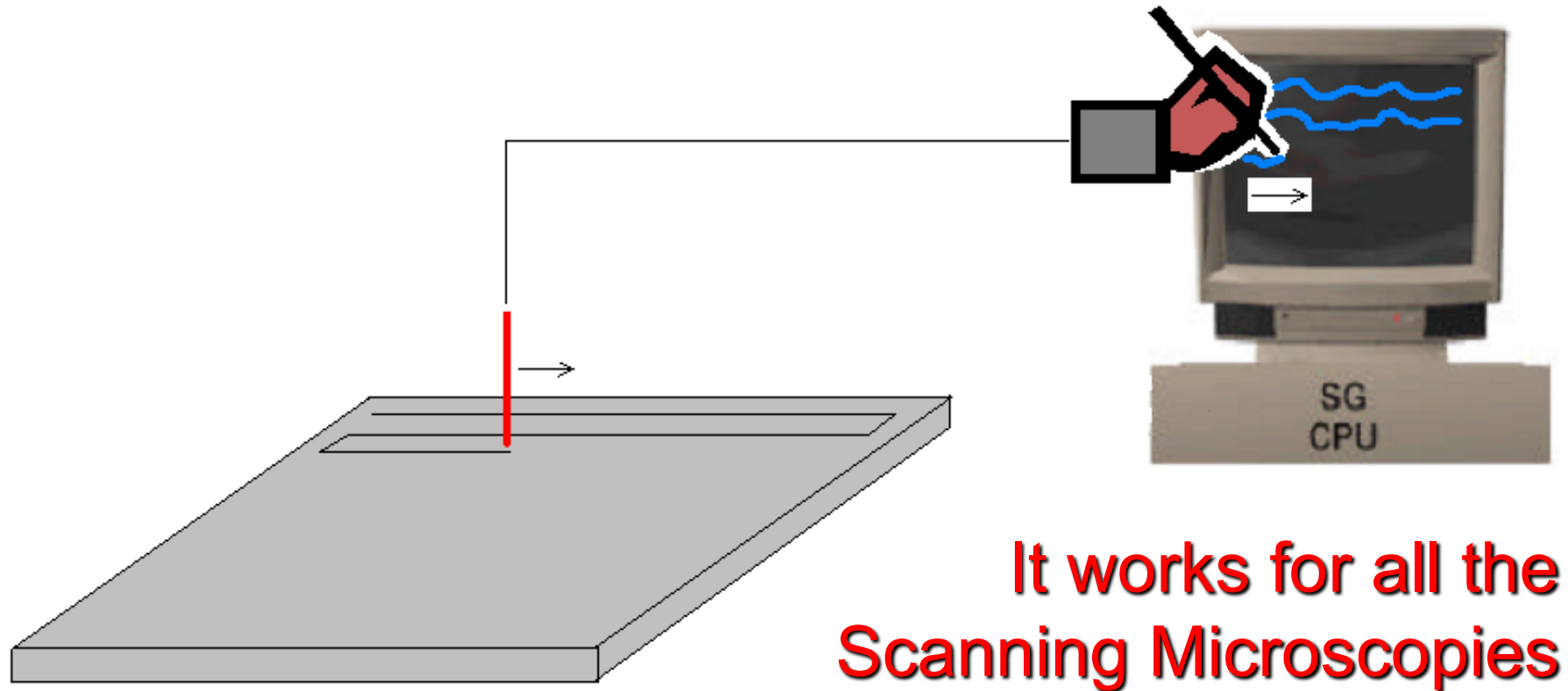
How to monitor the self-
assembly process?

How to check the film quality?

Four different Microscopies

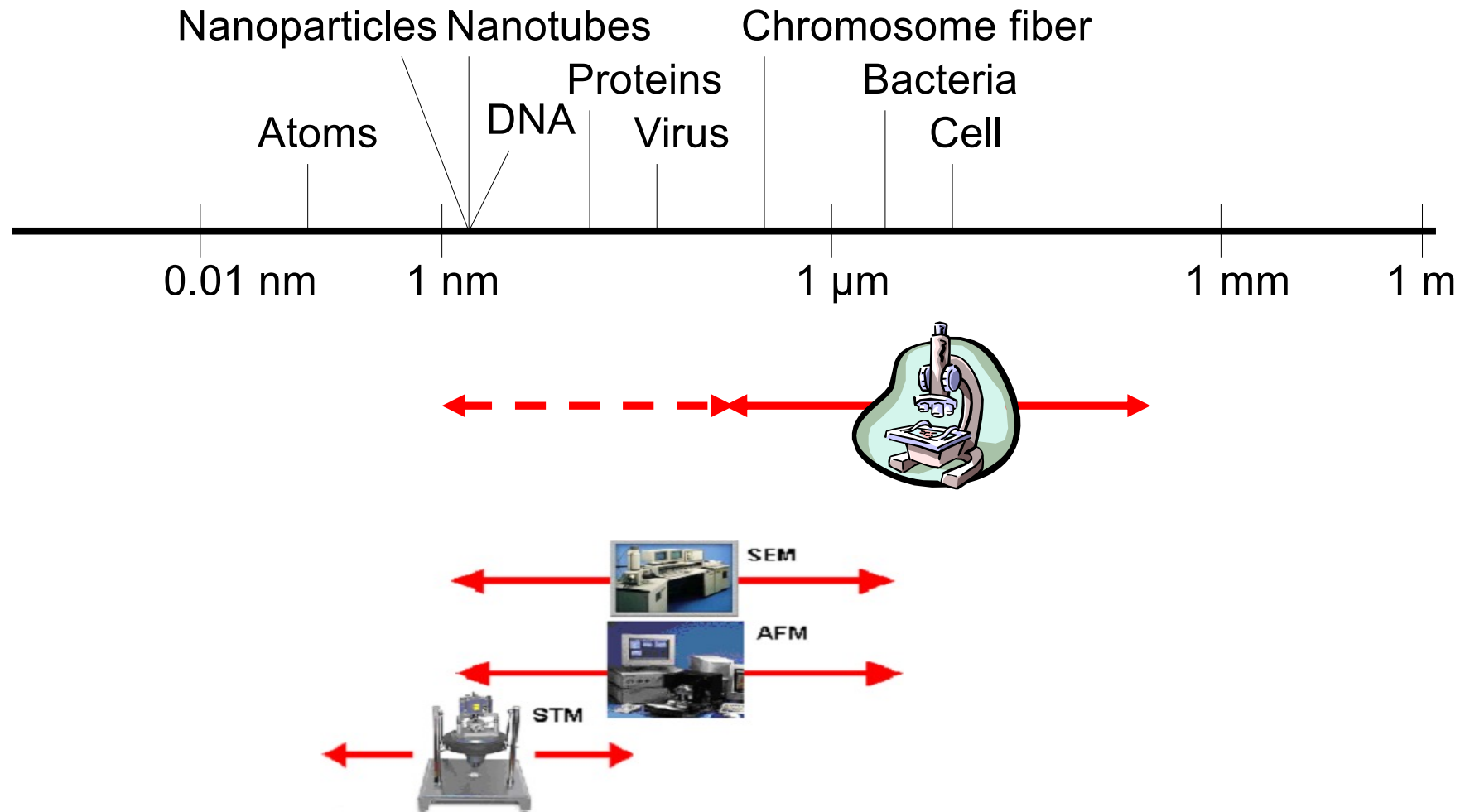
1. Transmission Electron Microscopy (**TEM**)
2. Scanning Electron Microscopy (**SEM**)
3. Atomic Force Microscopy (**AFM**)
4. Scanning Tunneling Microscopy (**STM**)

All are Scanning Microscopies



The sample scanning generates an image visualized
with computer graphic tools

SEM Microscopy



Electron Microscopies

Scanning
Electron
Microscopy

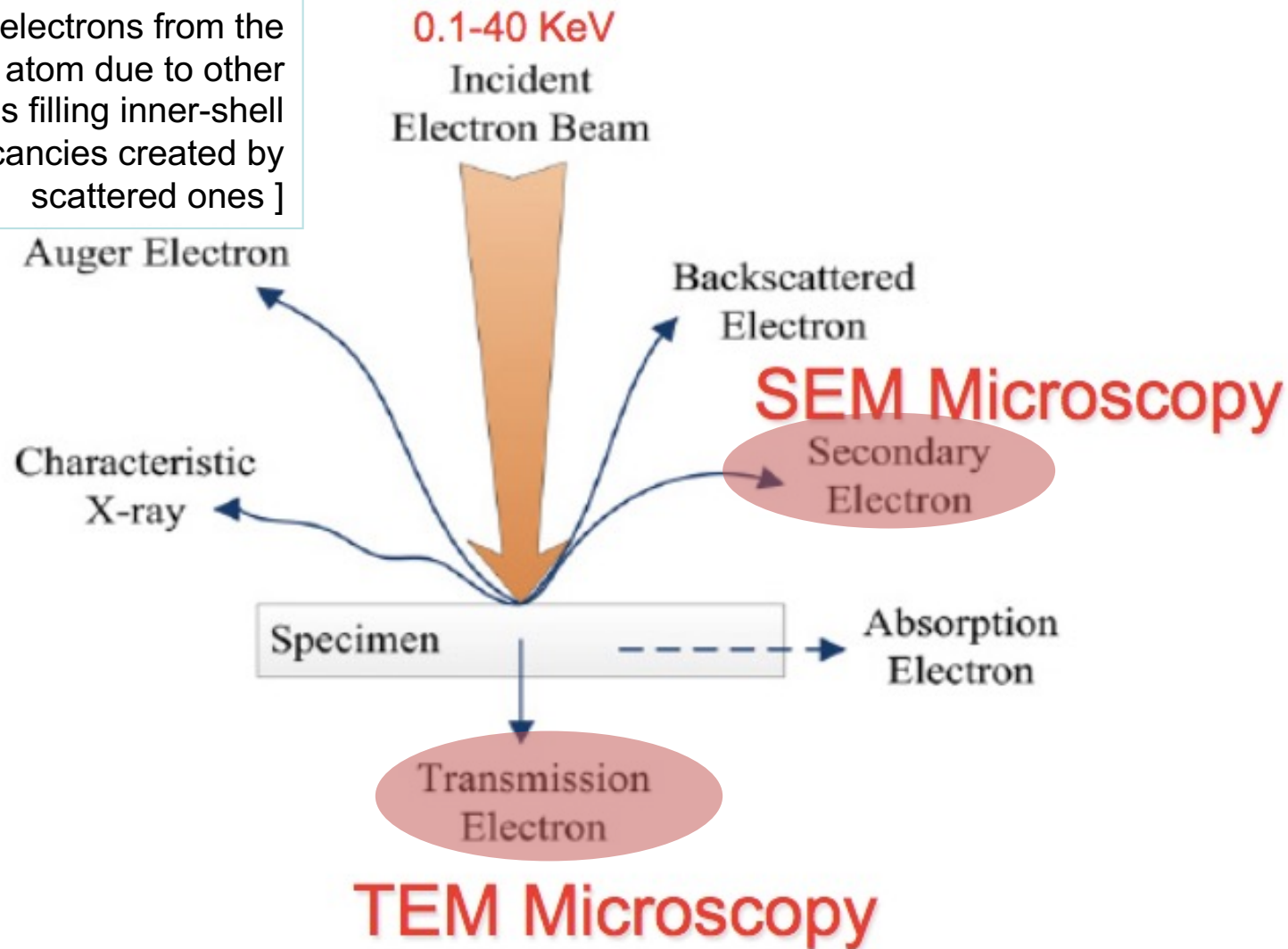


Transmission
Electron
Microscopy

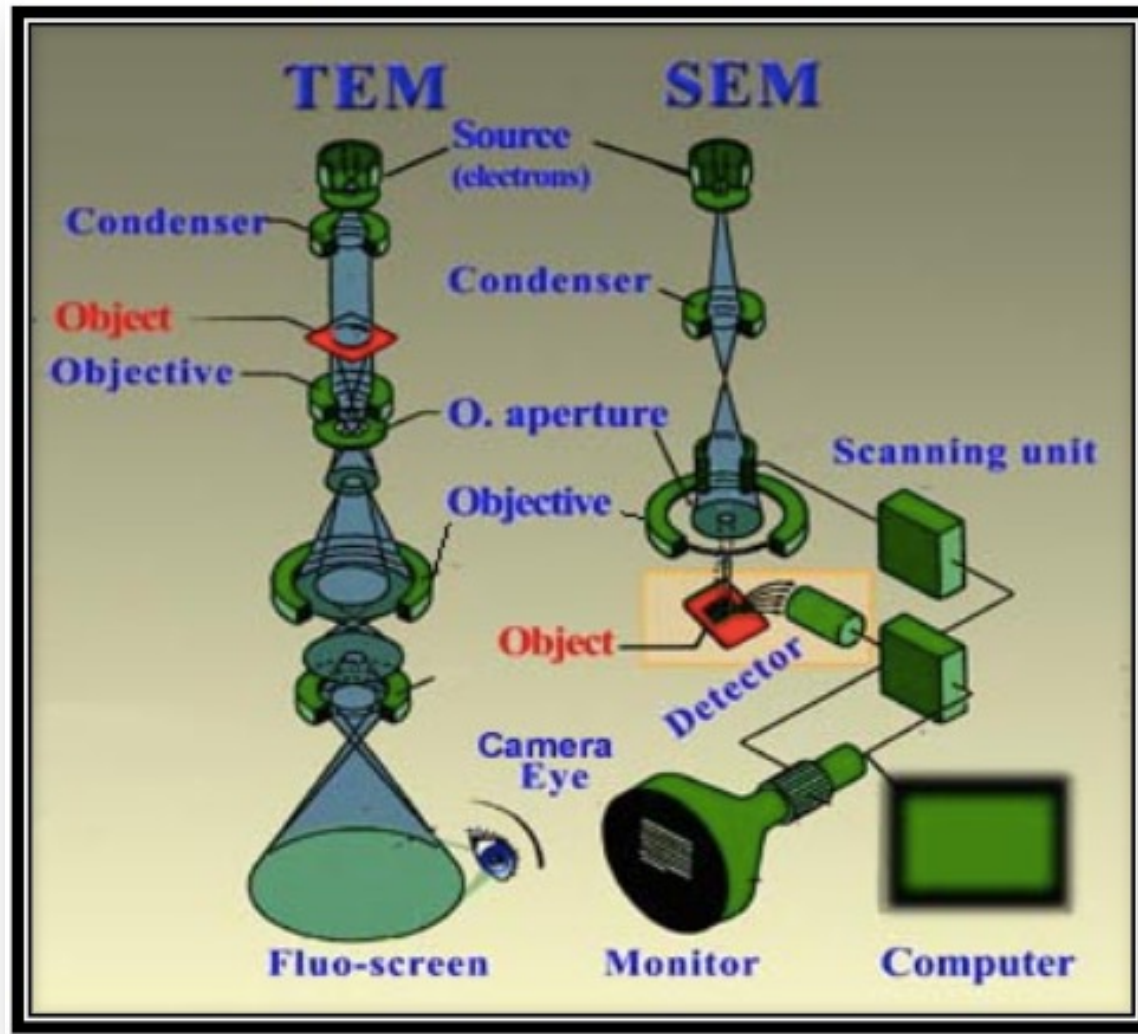


Electron Microscopy Principle

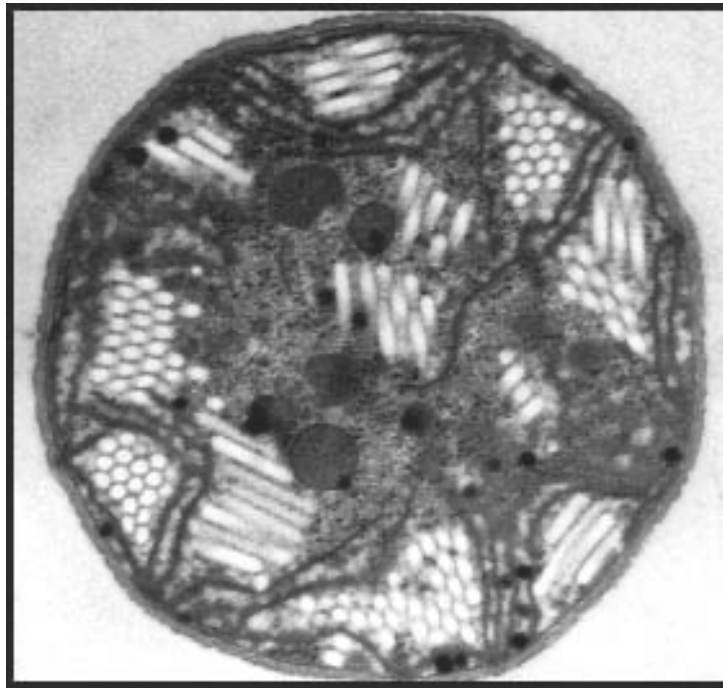
[Emitted electrons from the same atom due to other electrons filling inner-shell vacancies created by scattered ones]



Electron Microscopies

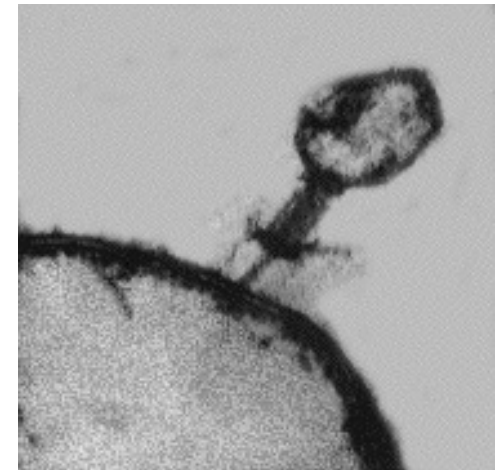
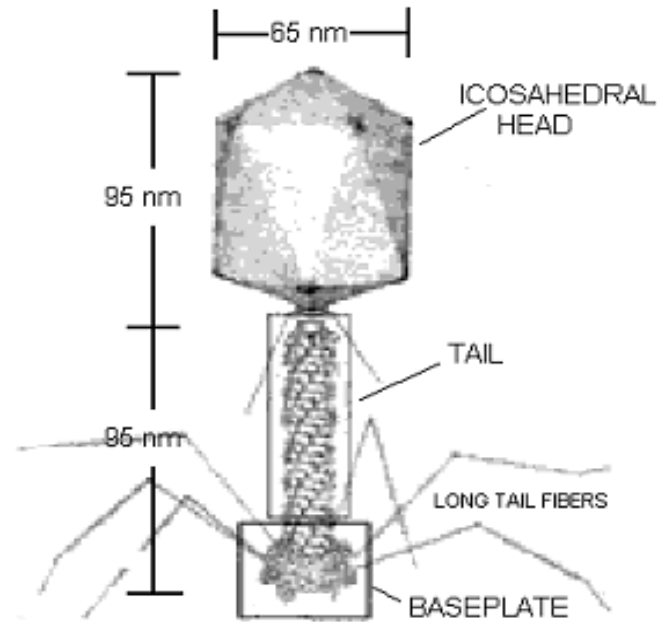


TEM Imaging



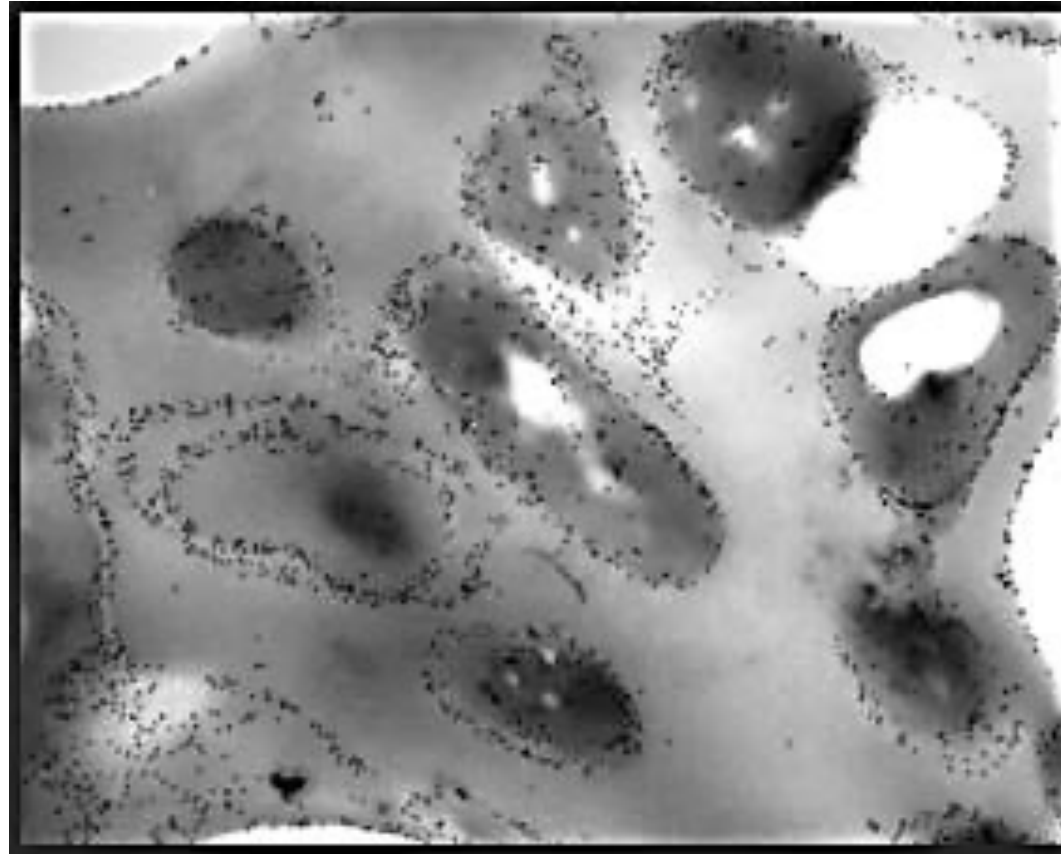
Cell of Cyanobacteria Microcystis by TEM

TEM Imaging



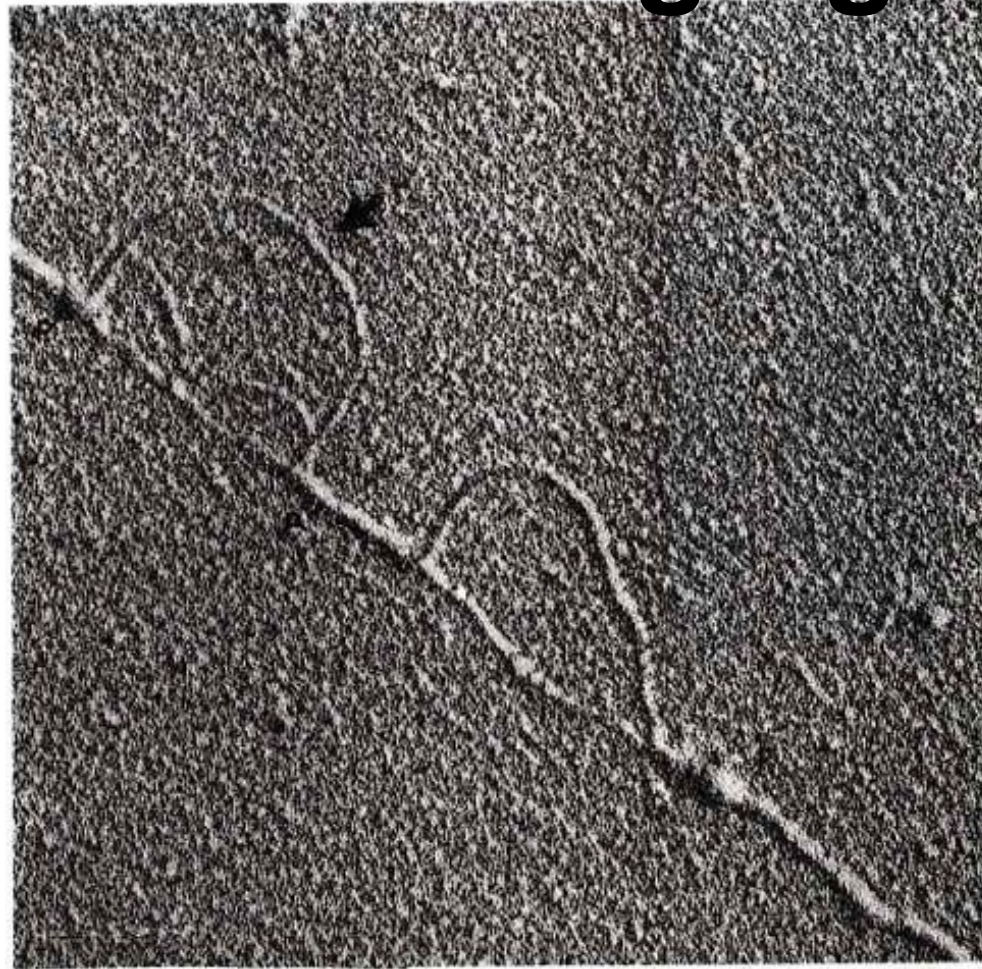
Virus T4 Bacteriophages

SEM Imaging



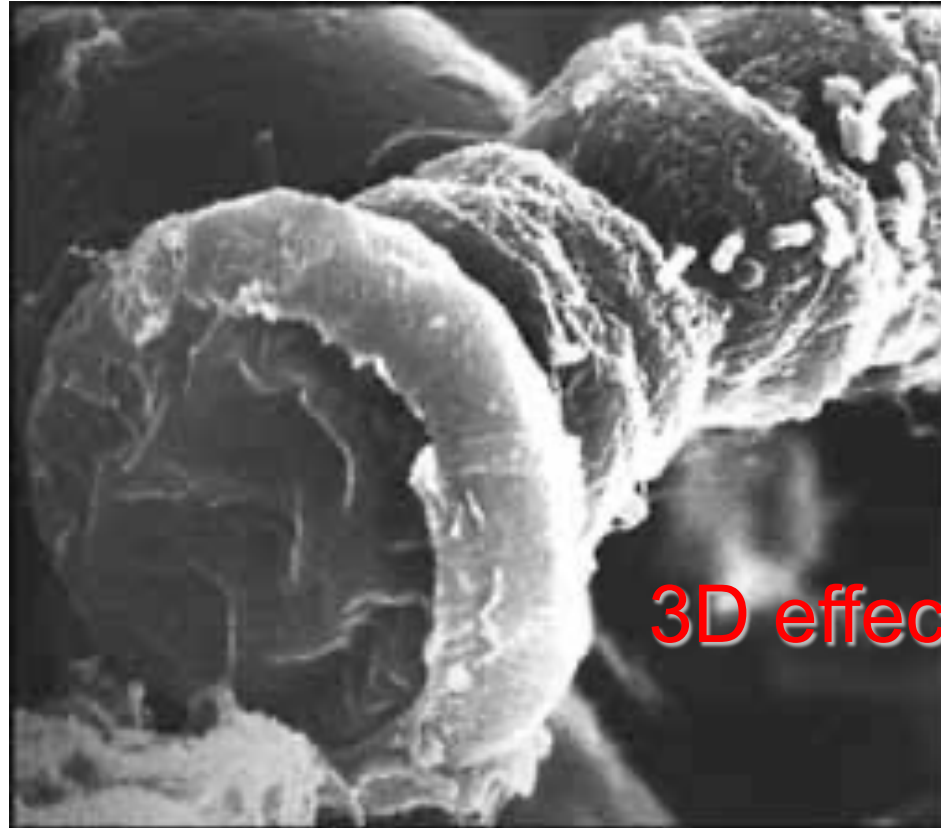
Antigens localized on the surface
of bacteria cells

SEM Imaging



Isolated Chromatin (DNA-macromolecules including hystons and not-hystons proteins) of about 30 nm and with small filament

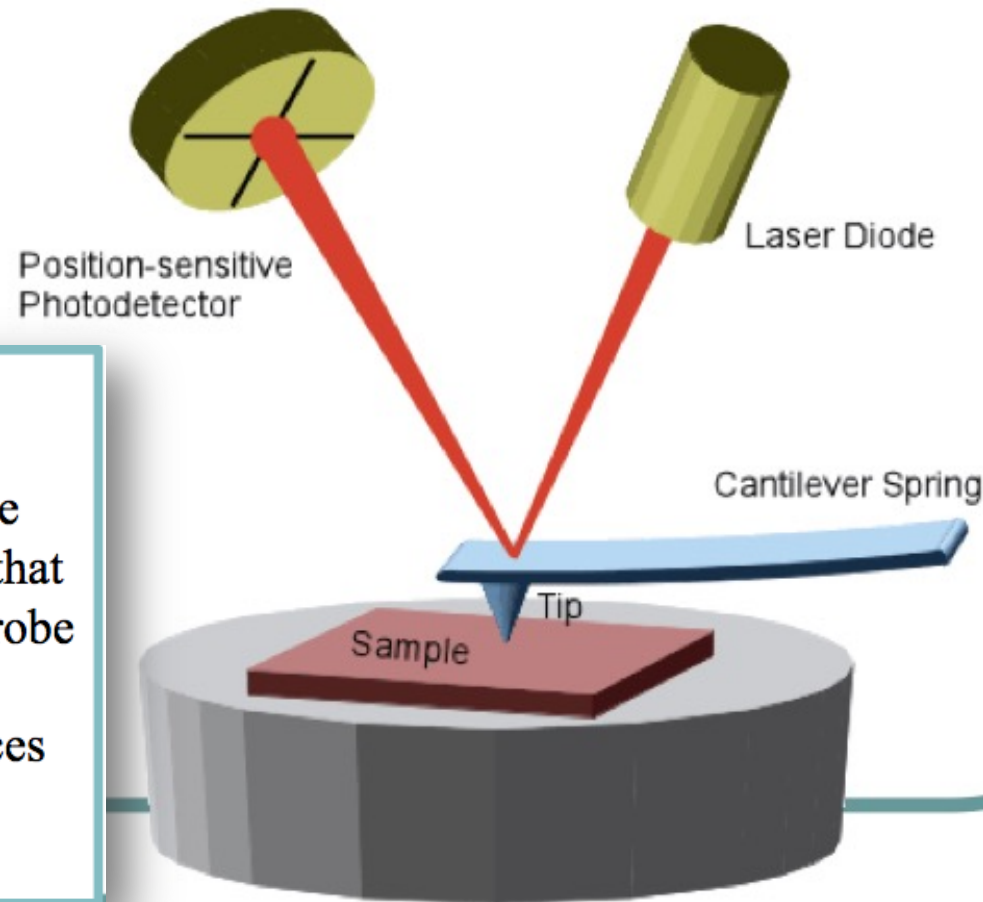
SEM Imaging



3D effect on SEM

End part of Nodularia
(cyanobacteria in filament shape)

AFM detection principle

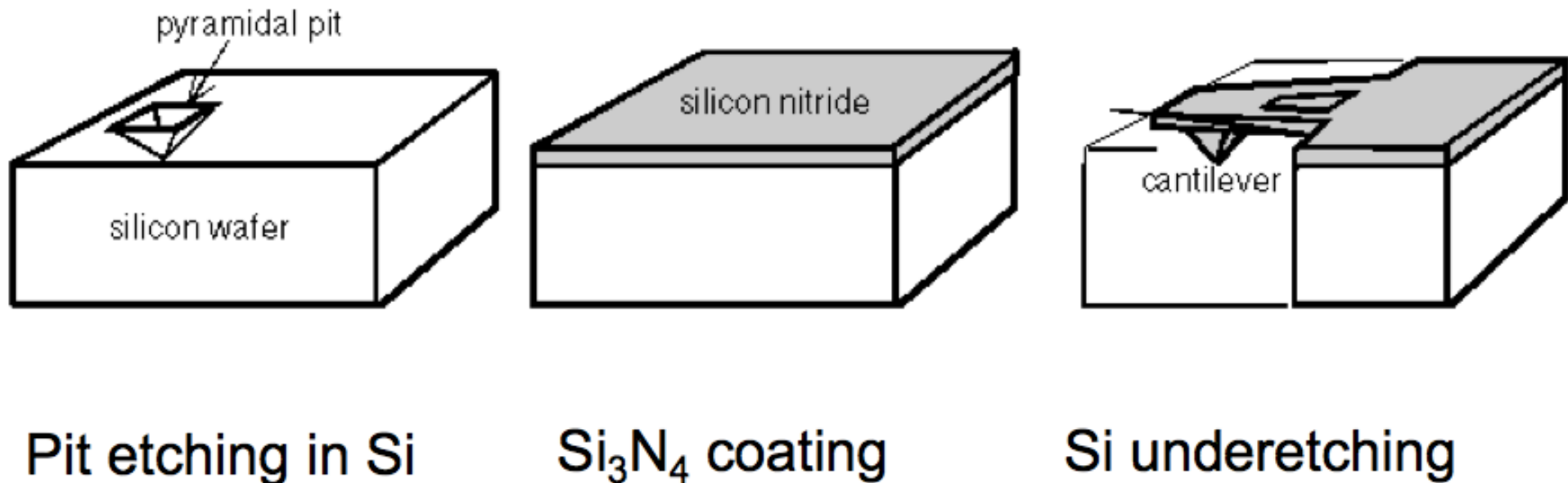


3 major abilities:

1. force measurement between probe-sample
2. imaging from forces that sample imposes on probe (3D, pseudocolor)
3. manipulation use forces to change sample properties

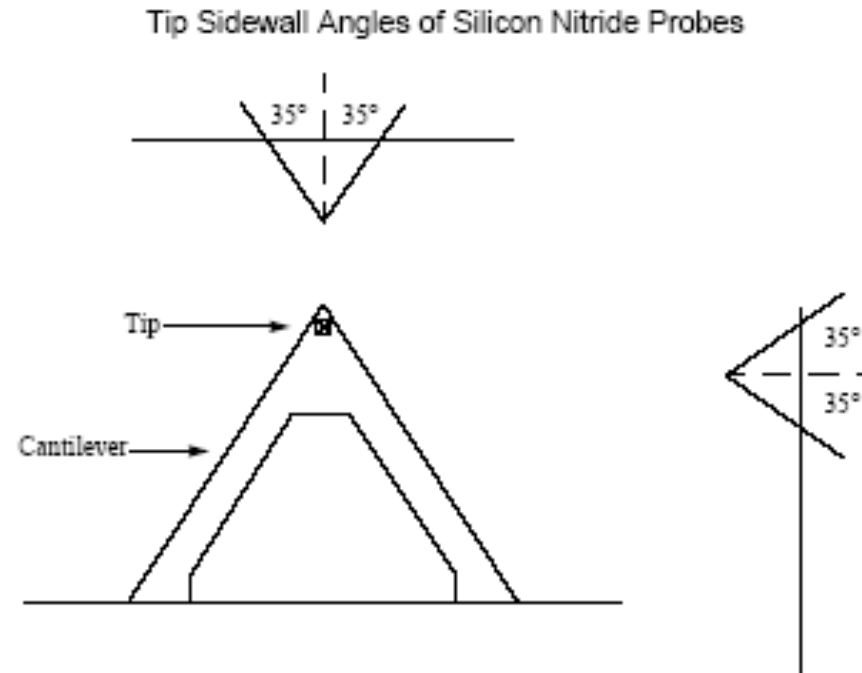
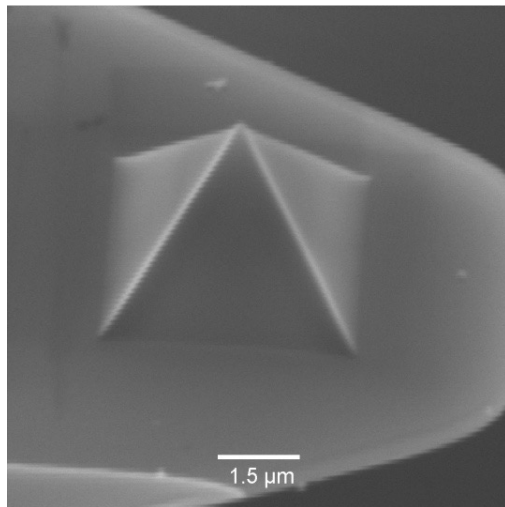
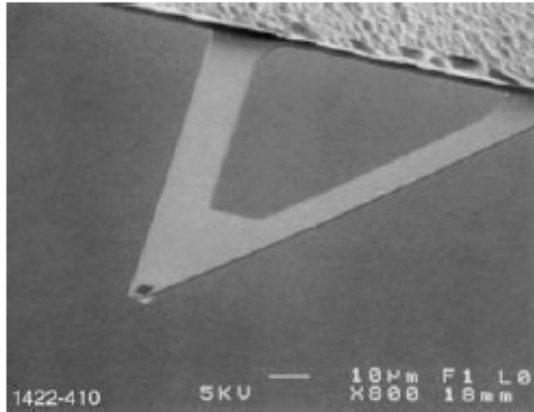
Detection principle is obtained by monitoring the bending of the cantiliver that host the tip

AFM Tip fabrication

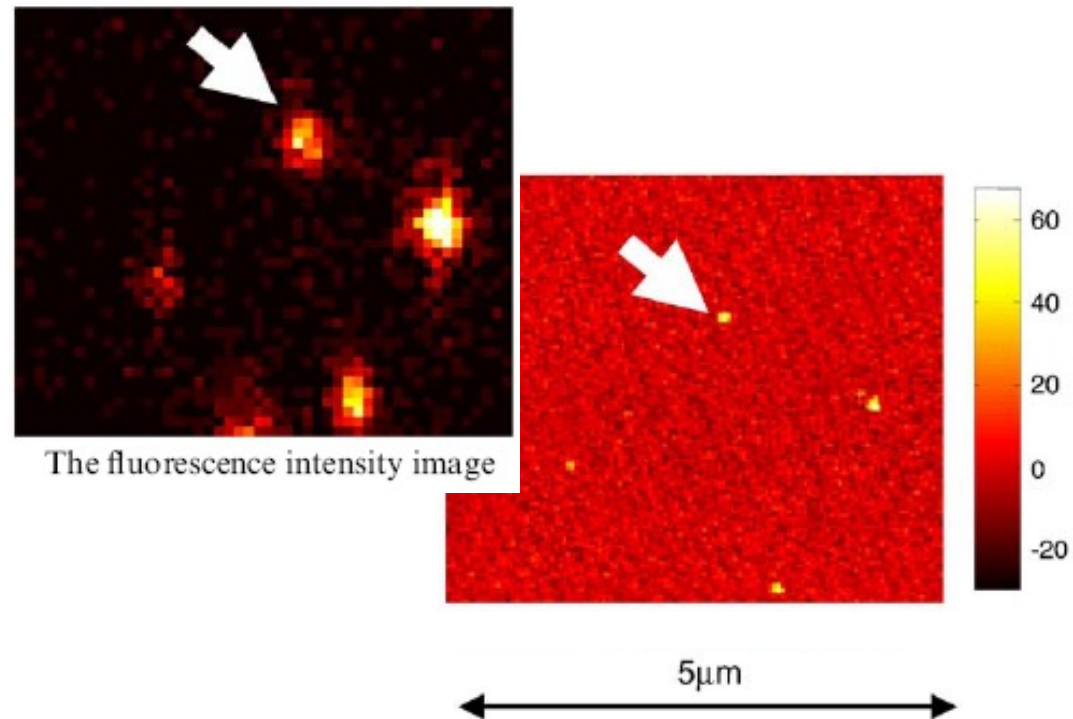


AFM tips are typically sculpted on silicon wafers

SEM on Silicon nitride probes

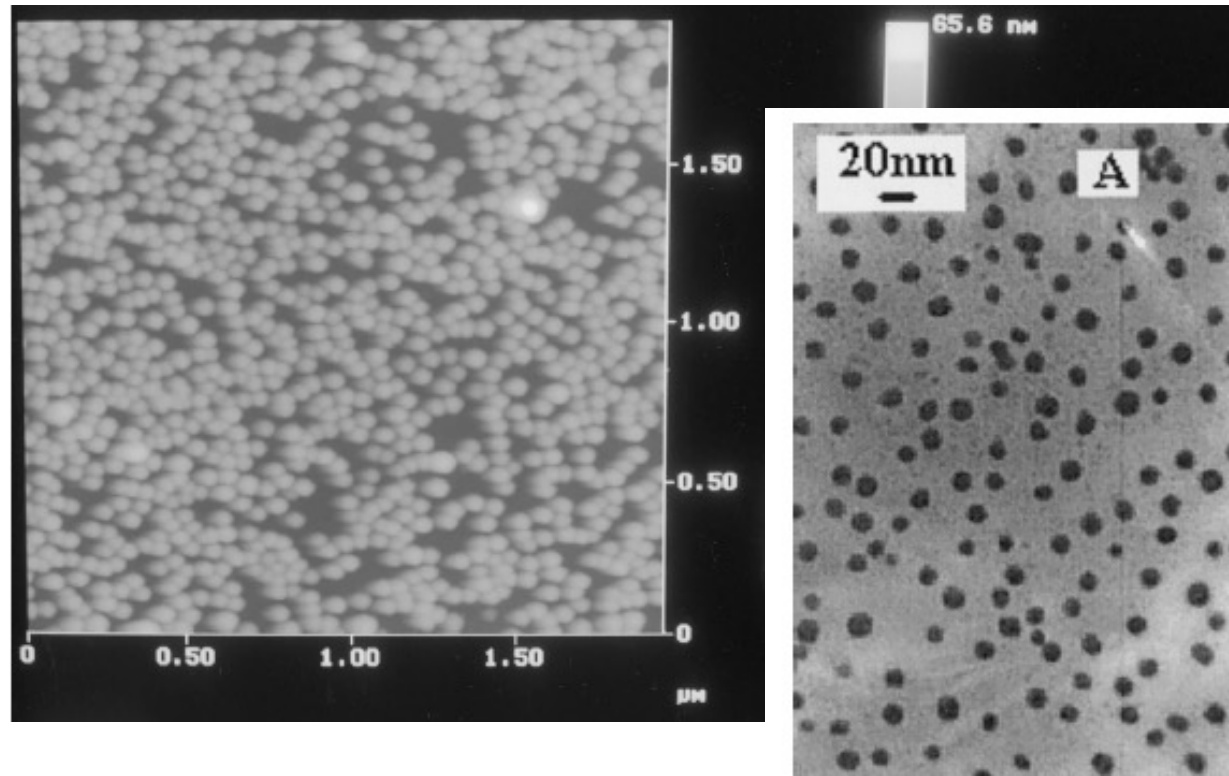


Optics versus AFM



Fluorescent Nanoparticles with average size of about 40 nm

AFM Imaging

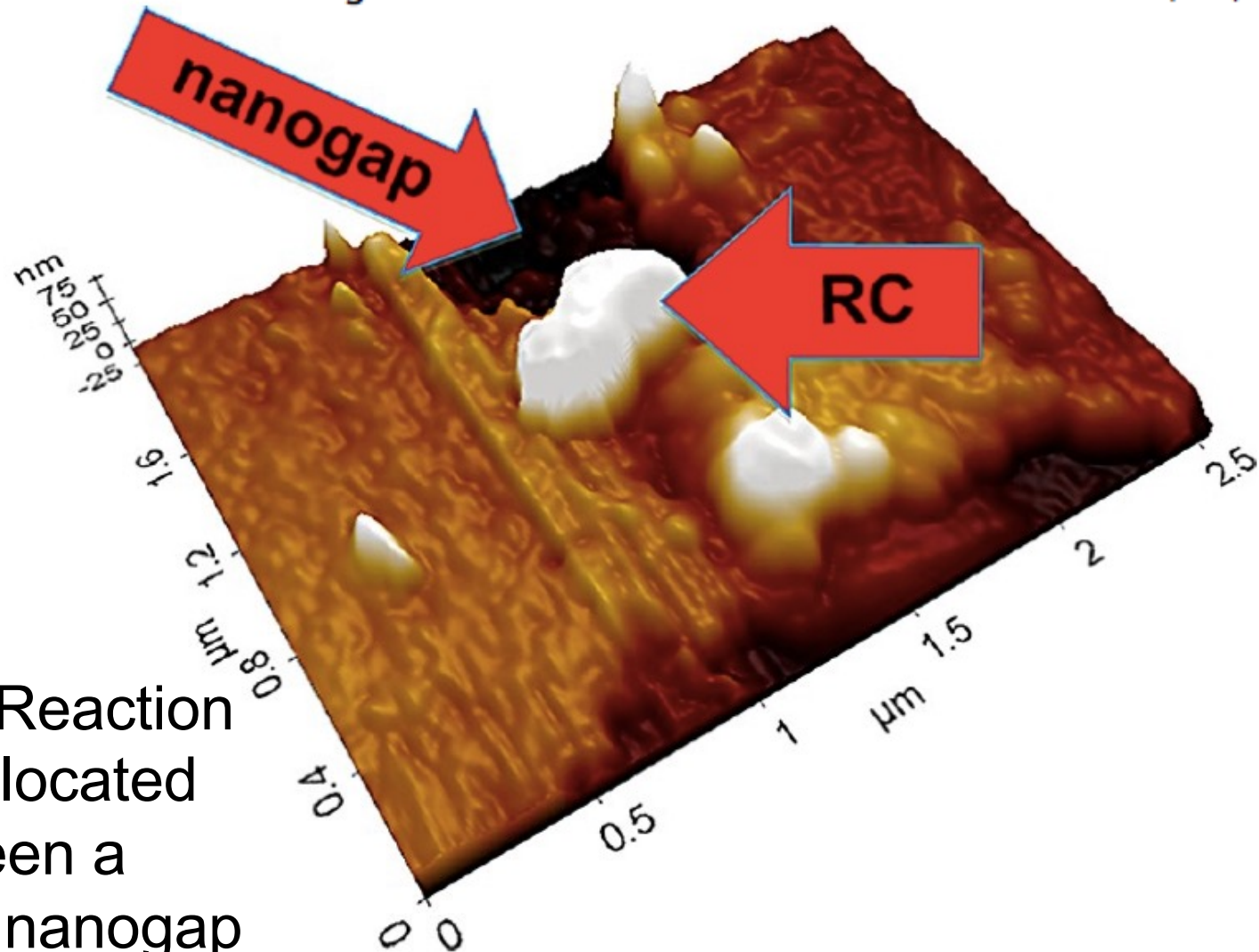


TEM images

Gold nanoparticles made off gold core and a
thiols-shell to stabilize the particle

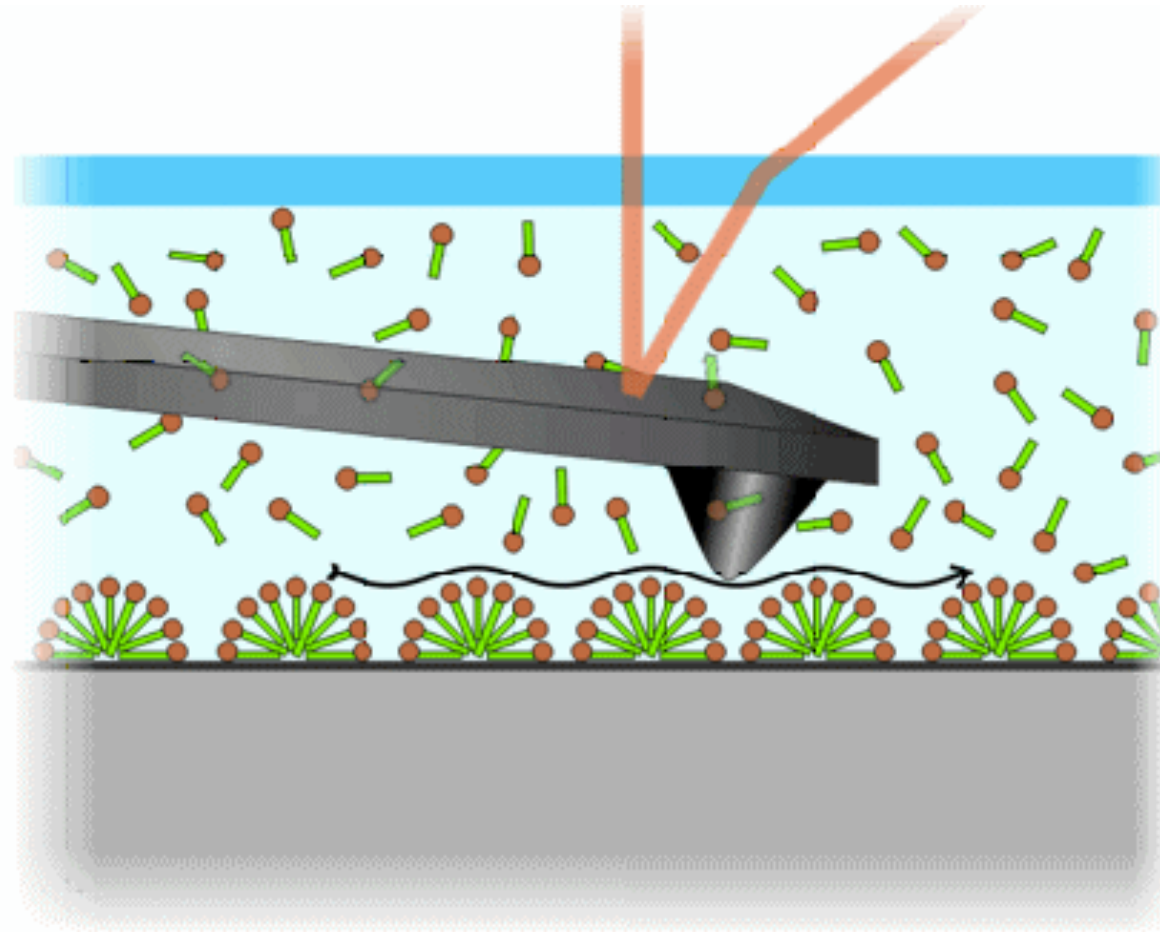
AFM Imaging in Air

[dx.doi.org/10.1021/bm301063m](https://doi.org/10.1021/bm301063m) | *Biomacromolecules* 2012, 13, 3503–3509



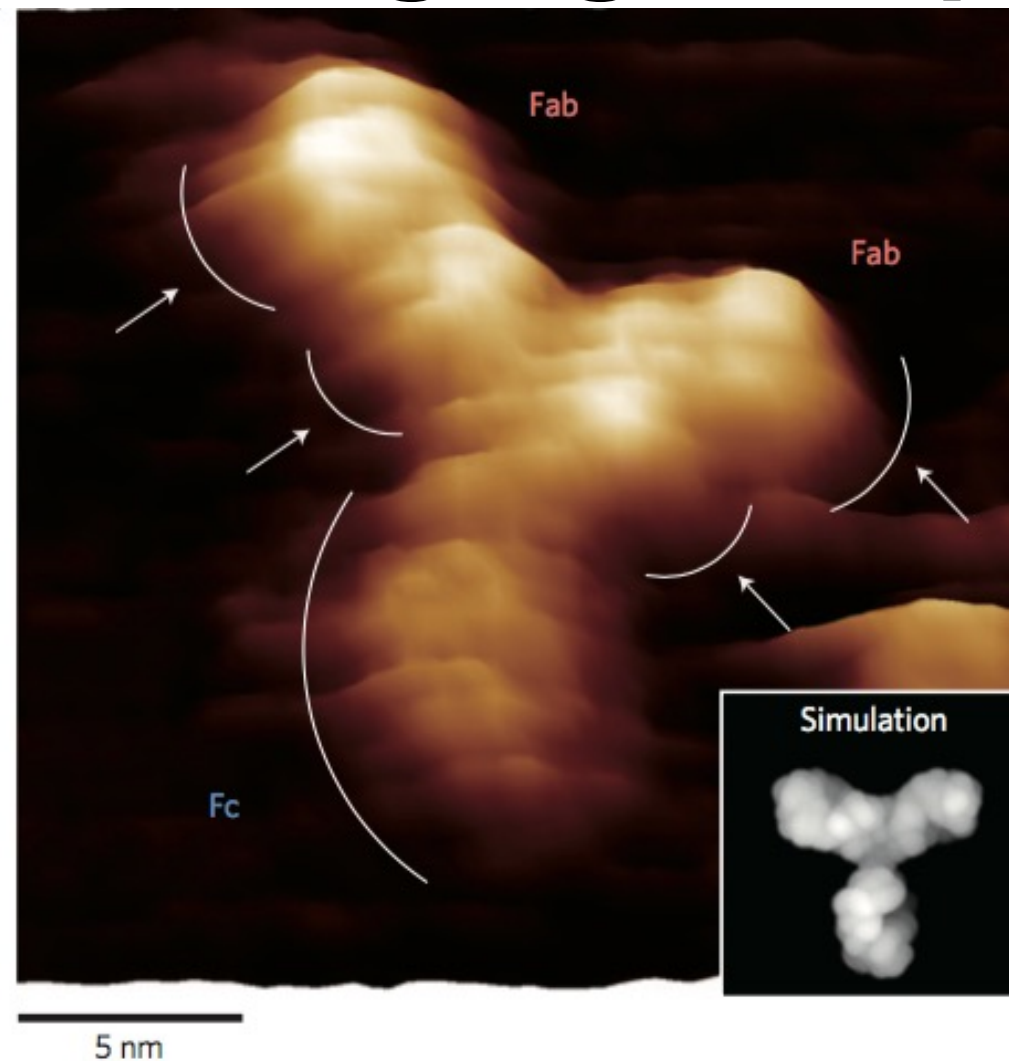
A protein (Reaction Center) located in between a metallic nanogap

AFM in liquid



AFM is also used fully in water for imaging typically biological systems in their native environments

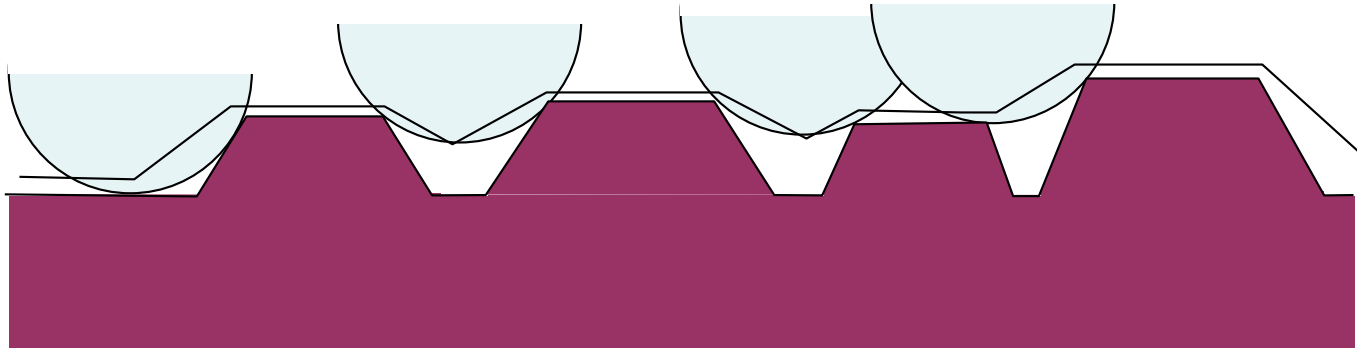
AFM Imaging in liquid



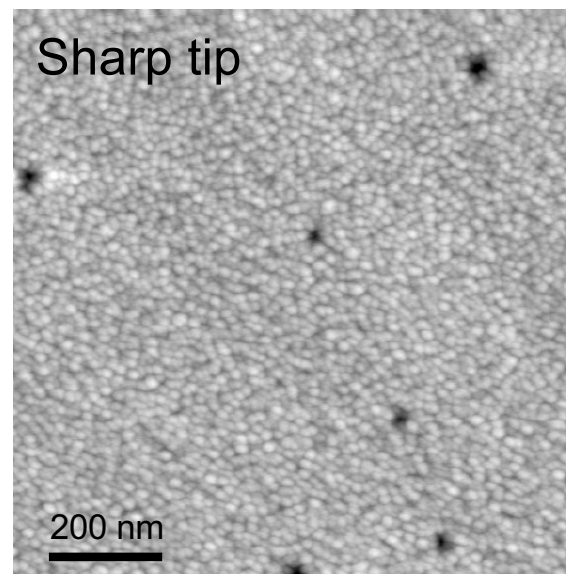
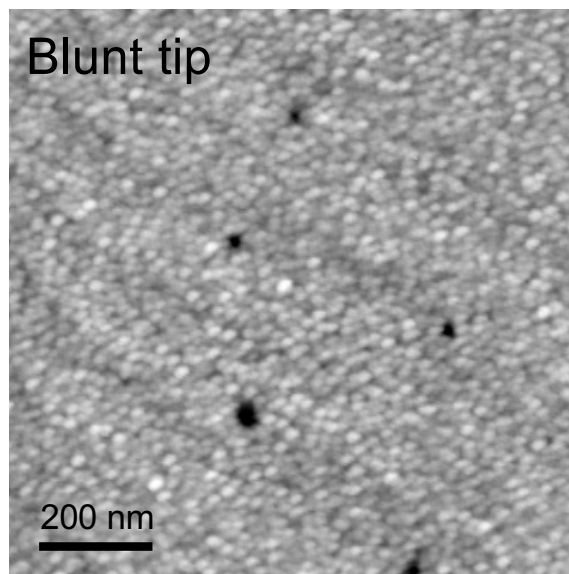
AFM imaging on Antibodies

(c) S.Carrara

Dense nanostructure arrays

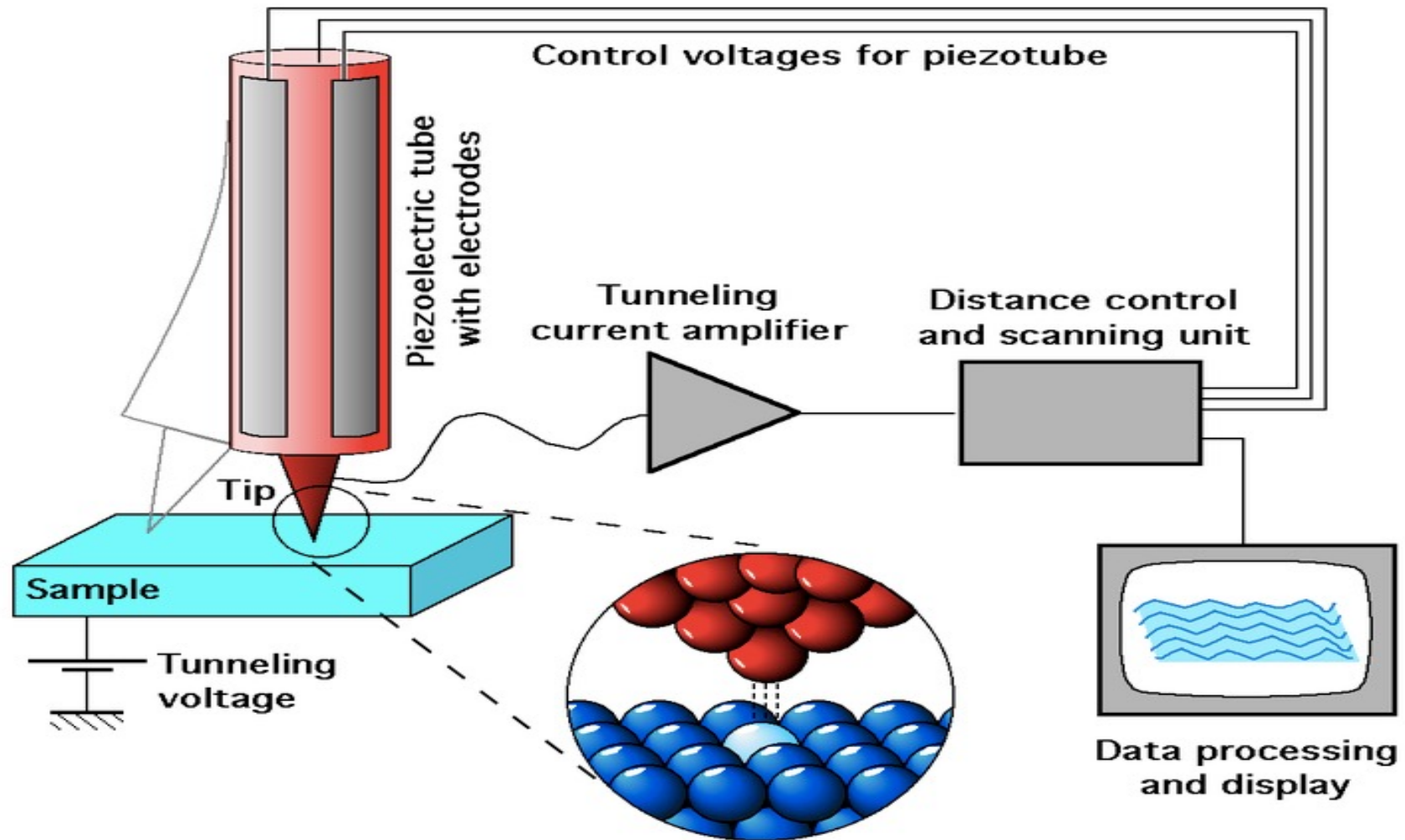


For densely packed features the tip size can also cause errors in determining the height of the islands, or the overall appearance of the surface



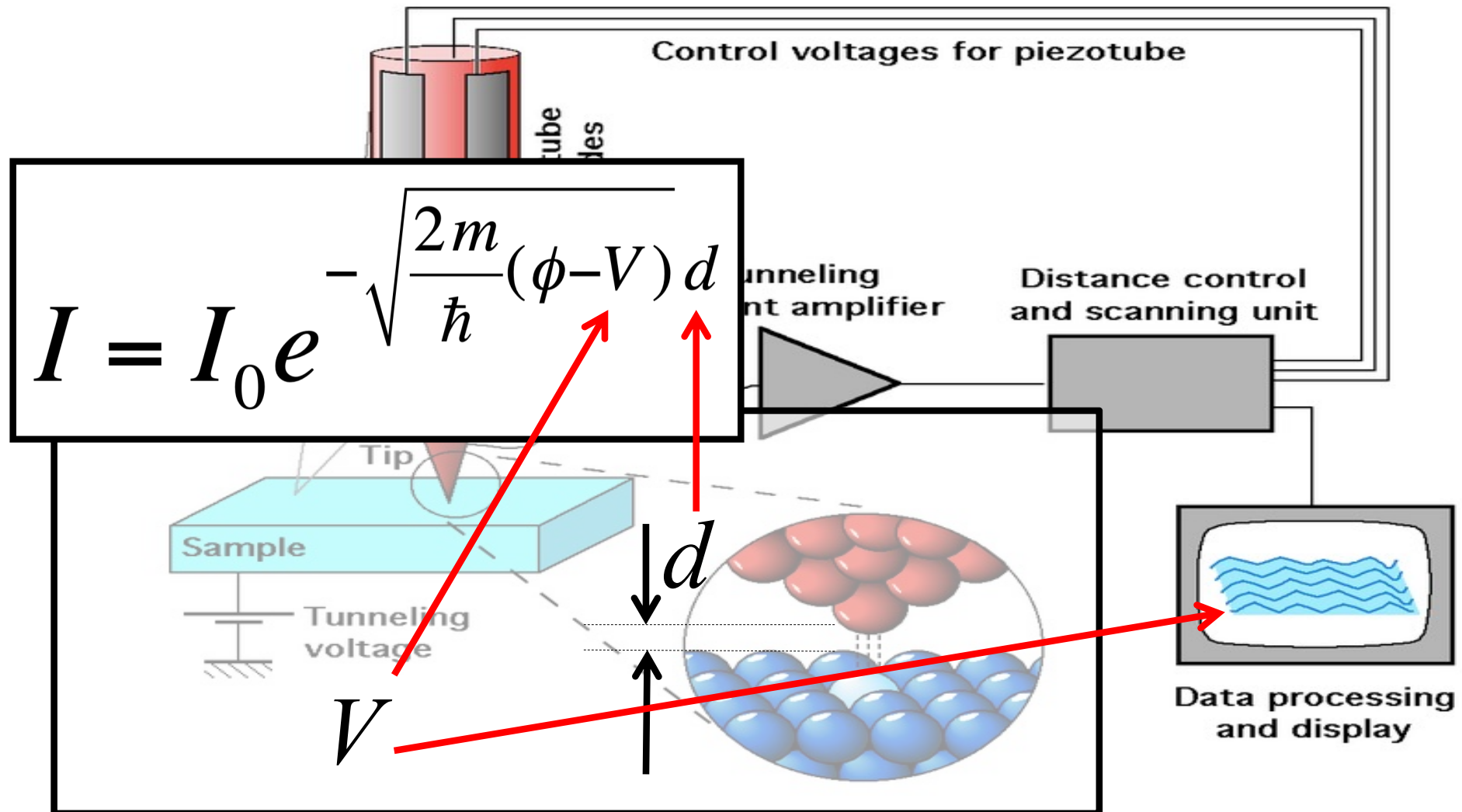
(credit by Cambridge University)

STM Microscopy



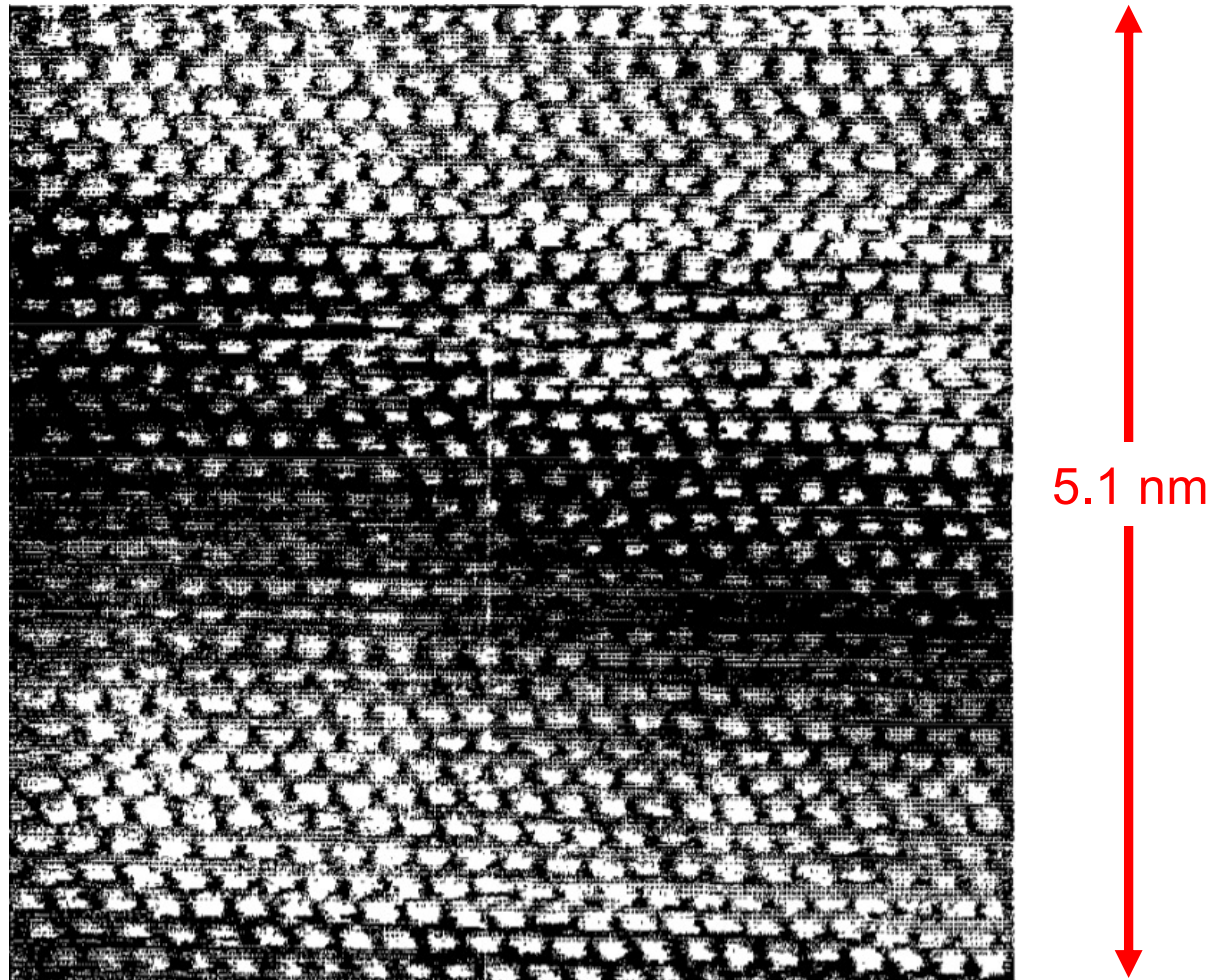
The STM Microscopy is based on tunneling currents as established in between the tip and the sample

STM Microscopy



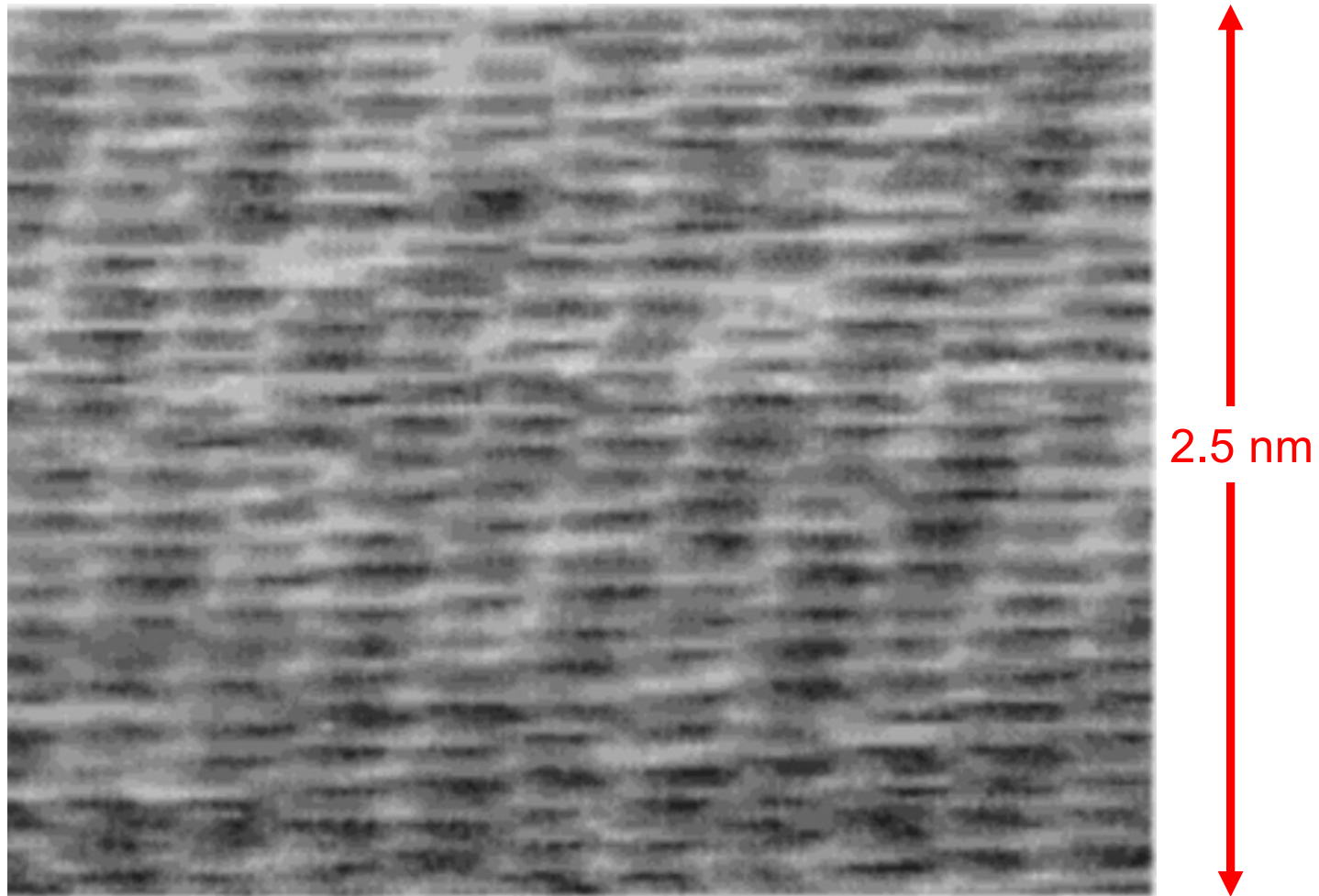
The STM Microscopy is based on tunneling currents as established in between the tip and the sample

STM imaging



Carbon atoms in the lattice structure of the highly oriented pyrolytic graphite. Image by STM in air.

STM imaging



Organic thiols self-assembled onto highly oriented pyrolytic graphite. Image by STM in air.